

TLV2422, TLV2422A, TLV2422Y

Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT

WIDE-INPUT-VOLTAGE MICROPOWER DUAL OPERATIONAL AMPLIFIERS

SLOS199C – SEPTEMBER 1997 – REVISED APRIL 2001

- Output Swing Includes Both Supply Rails
- Extended Common-Mode Input Voltage Range . . . 0 V to 4.5 V (Min) With 5-V Single Supply
- No Phase Inversion
- Low Noise . . . 18 nV/√Hz Typ at f = 1 kHz
- Low Input Offset Voltage
950 μV Max at T_A = 25°C (TLV2422A)
- Low Input Bias Current . . . 1 pA Typ
- Micropower Operation . . . 50 μA Per Channel
- 600-Ω Output Drive
- Available in Q-Temp Automotive
HighRel Automotive Applications
Configuration Control / Print Support
Qualification to Automotive Standards

description

The TLV2422 and TLV2422A are dual low-voltage operational amplifiers from Texas Instruments. The common-mode input voltage range for this device has been extended over the typical CMOS amplifiers making them suitable for a wide range of applications. In addition, the devices do not phase invert when the common-mode input is driven to the supply rails. This satisfies most design requirements without paying a premium for rail-to-rail input performance. They also exhibit rail-to-rail output performance for increased dynamic range in single- or split-supply applications. This family is fully characterized at 3-V and 5-V supplies and is optimized for low-voltage operation. The TLV2422 only requires 50 μA of supply current per channel, making it ideal for battery-powered applications. The TLV2422 also has increased output drive over previous rail-to-rail operational amplifiers and can drive 600-Ω loads for telecom applications.

Other members in the TLV2422 family are the high-power, TLV2442, and low-power, TLV2432, versions.

The TLV2422, exhibiting high input impedance and low noise, is excellent for small-signal conditioning for high-impedance sources, such as piezoelectric transducers. Because of the micropower dissipation levels and low-voltage operation, these devices work well in hand-held monitoring and remote-sensing applications. In addition, the rail-to-rail output feature with single- or split-supplies makes this family a great choice when interfacing with analog-to-digital converters (ADCs). For precision applications, the TLV2422A is available with a maximum input offset voltage of 950 μV.

If the design requires single operational amplifiers, see the TI TLV2211/21/31. This is a family of rail-to-rail output operational amplifiers in the SOT-23 package. Their small size and low power consumption, make them ideal for high density, battery-powered equipment.

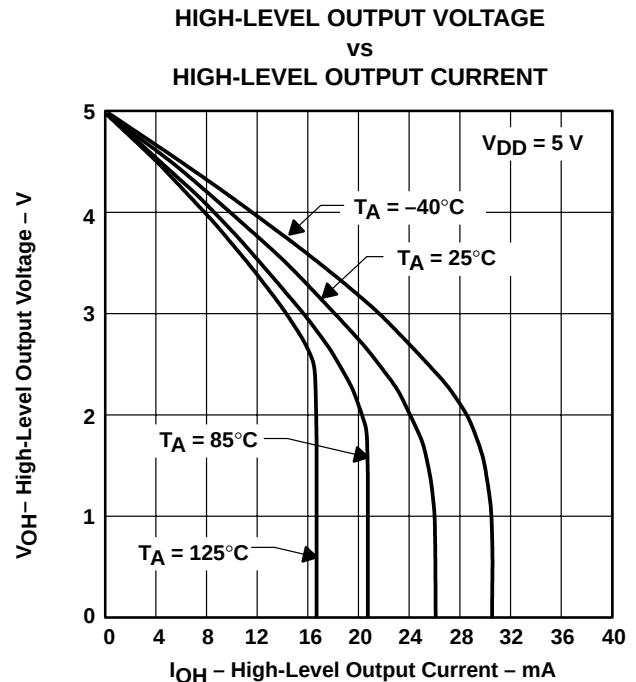


Figure 1



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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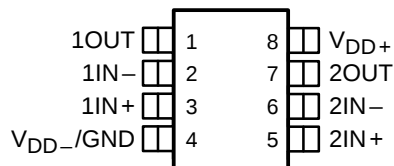
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AVAILABLE OPTIONS

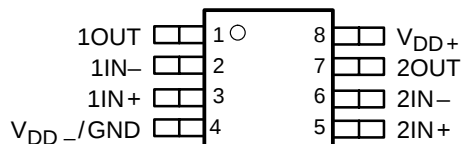
T _A	V _{IO} max AT 25°C	PACKAGED DEVICES					CHIP FORM (Y)
		SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	TSSOP (PW)	CERAMIC FLAT PACK (U)	
0°C to 70°C	2.5 mV	TLV2422CD	—	—	TLV2422CPWLE	—	TLV2422Y
–40°C to 85°C	950 µV 2.5 mV	TLV2422AID TLV2422ID	— —	— —	TLV2422AIPWLE —	— —	
–40°C to 125°C	950 µV 2.5 mV	TLV2422AQD TLV2422QD	— —	— —	— —	— —	
–55°C to 125°C	950 µV 2 mV	— —	TLV2422AMFK TLV2422MFK	TLV2422AMJG TLV2422MJG	— —	TLV2422AMU TLV2422MU	

The D packages are available taped and reeled. Add R suffix to device type (e.g., TLV2422CDR). The PW package is available only left-end taped and reeled. Chips are tested at 25°C.

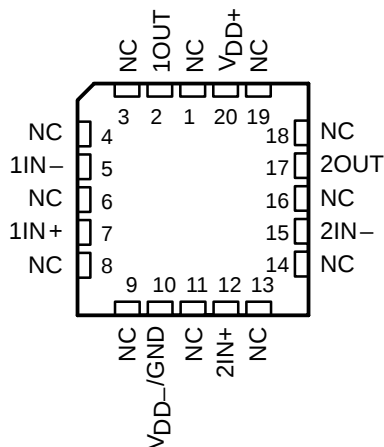
D OR JG PACKAGE (TOP VIEW)



PW PACKAGE (TOP VIEW)

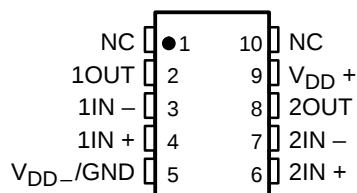


FK PACKAGE (TOP VIEW)



NC – No internal connection

U PACKAGE (TOP VIEW)

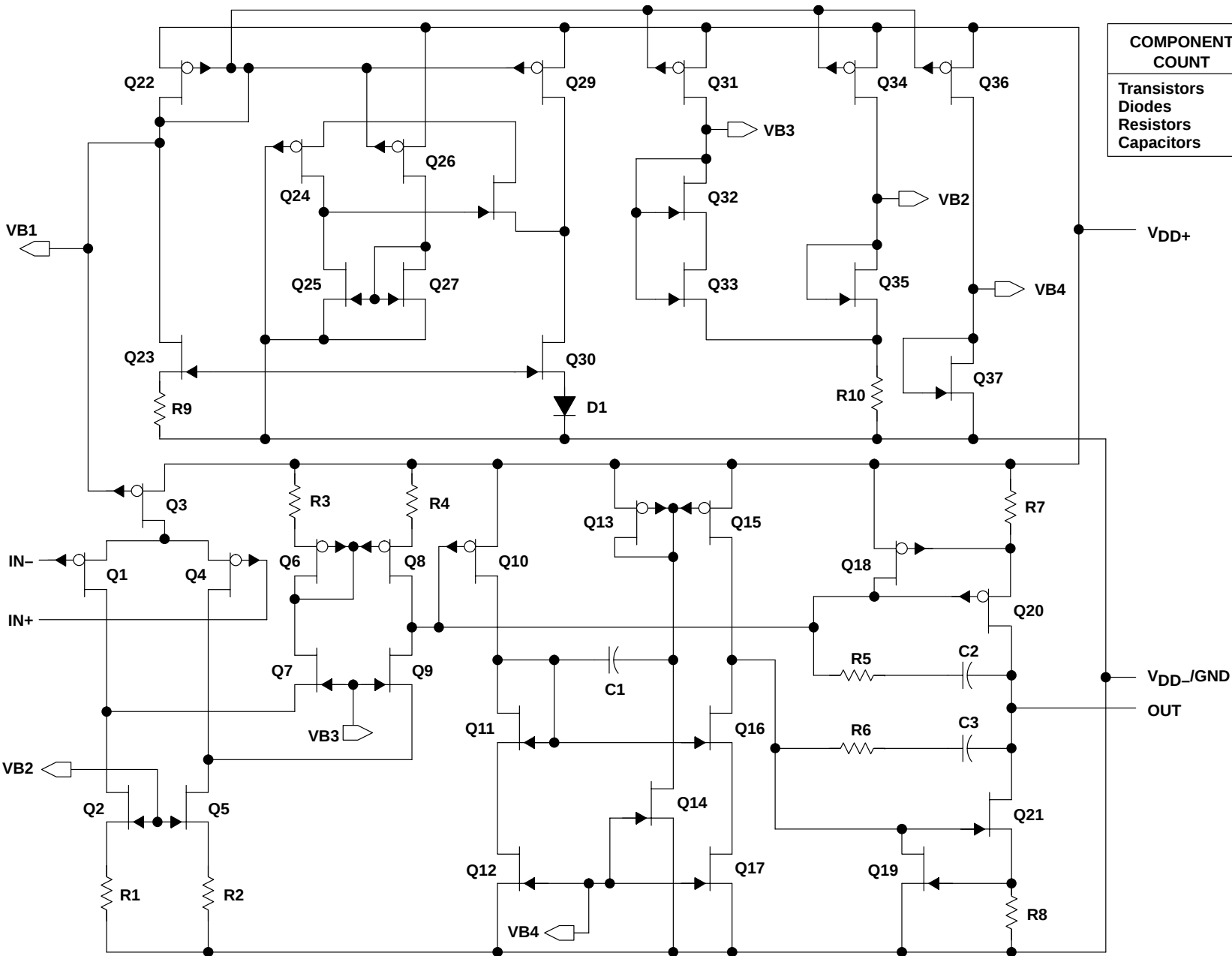


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COMPONENT COUNT	
Transistors	69
Diodes	5
Resistors	26
Capacitors	6

equivalent schematic (each amplifier)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V_{DD} (see Note 1)	12 V
Differential input voltage, V_{ID} (see Note 2)	$\pm V_{DD}$
Input voltage, V_I (any input, see Note 1): C and I suffix	-0.3 V to V_{DD}
Input current, I_I (each input)	± 5 mA
Output current, I_O	± 50 mA
Total current into V_{DD+}	± 50 mA
Total current out of V_{DD-}	± 50 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A : C suffix	0°C to 70°C
I suffix	-40°C to 85°C
Q suffix	-40°C to 125°C
M suffix	-55°C to 125°C
Storage temperature range, T_{stg}	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{DD+} and V_{DD-} .
2. Differential voltages are at $IN+$ with respect to $IN-$. Excessive current flows if input is brought below $V_{DD-} - 0.3$ V.
3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW
FK	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	546 mW	210 mW
PW	525 mW	4.2 mW/°C	336 mW	273 mW	105 mW
U	675 mW	5.4 mW/°C	432 mW	350 mW	135 mW

recommended operating conditions

	C SUFFIX		I SUFFIX		Q SUFFIX		M SUFFIX		UNIT
	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Supply voltage, $V_{DD\pm}$	2.7	10	2.7	10	2.7	10	2.7	10	V
Input voltage range, V_I	V_{DD-}	$V_{DD+} - 0.8$	V_{DD-}	$V_{DD+} - 0.8$	V_{DD-}	$V_{DD+} - 0.8$	V_{DD-}	$V_{DD+} - 0.8$	V
Common-mode input voltage, V_{IC}	V_{DD-}	$V_{DD+} - 0.8$	V_{DD-}	$V_{DD+} - 0.8$	V_{DD-}	$V_{DD+} - 0.8$	V_{DD-}	$V_{DD+} - 0.8$	V
Operating free-air temperature, T_A	0	70	-40	85	-40	125	-55	125	°C



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electrical characteristics at specified free-air temperature, $V_{DD} = 3\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLV2422C			UNIT
			MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, V_{DD} \pm \pm 2.5\text{ V}, R_S = 50\ \Omega$	25°C		300	2000	μV
		Full range			2500	
α_{VIO} Temperature coefficient of input offset voltage		25°C to 70°C		2		$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C		0.003		$\mu\text{V}/\text{mo}$
I_{IO} Input offset current		25°C		0.5	60	pA
		Full range			150	
I_{IB} Input bias current		25°C		1	60	pA
		Full range			150	
V_{ICR} Common-mode input voltage range		25°C	0 to 2.5	-0.25 to 2.75		V
		Full range	0 to 2.2			
V_{OH} High-level output voltage	$I_{OH} = -100\ \mu\text{A}$	25°C		2.97		V
	$I_{OH} = -500\ \mu\text{A}$	25°C		2.75		
		Full range		2.5		
V_{OL} Low-level output voltage	$V_{IC} = 0, I_{OL} = 100\ \mu\text{A}$	25°C		0.05		V
	$V_{IC} = 0, I_{OL} = 250\ \mu\text{A}$	25°C		0.2		
		Full range		0.5		
A_{VD} Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}, V_O = 1\text{ V to }2\text{ V}$	25°C	6	10		V/mV
		Full range	3			
		25°C		700		
$r_{i(d)}$ Differential input resistance		25°C		10^{12}		Ω
$r_{i(c)}$ Common-mode input resistance		25°C		10^{12}		Ω
$c_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$	25°C		8		pF
z_o Closed-loop output impedance	$f = 100\text{ kHz}, A_V = 10$	25°C		130		Ω
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to }2.5\text{ V}, V_O = 1.5\text{ V}, R_S = 50\ \Omega$	25°C	70	83		dB
		Full range	70			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 2.7\text{ V to }8\text{ V}, V_{IC} = V_{DD}/2, \text{ No load}$	25°C	80	95		dB
		Full range	80			
I_{DD} Supply current	$V_O = 1.5\text{ V}, \text{ No load}$	25°C		100	150	μA
		Full range			175	

† Full range is 0°C to 70°C.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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electrical characteristics at specified free-air temperature, $V_{DD} = 3\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	TLV2422I			TLV2422AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _{IC} = 0, V _O = 0, V _{DD} ± = ±2.5 V, R _S = 50 Ω		25°C	300 2000			300 950			μV
Full range				2500			1500				
αV _{IO}	Temperature coefficient of input offset voltage			25°C to 70°C	2			2			μV/°C
	Input offset voltage long-term drift (see Note 4)			25°C	0.003			0.003			μV/mo
I _{IO}	Input offset current			25°C	0.5 60			0.5 60			pA
Full range				150			150				
I _{IB}	Input bias current			25°C	1 60			1 60			pA
Full range				150			150				
V _{ICR}	Common-mode input voltage range	V _{IO} ≤ 5 mV, R _S = 50 Ω		25°C	0 to 2.5	–0.25 to 2.75	0 to 2.5		–0.25 to 2.75	V	
				Full range	0 to 2.2		0 to 2.2				
V _{OH}	High-level output voltage	I _{OH} = –100 μA		25°C	2.97			2.97			V
		I _{OH} = –500 μA		25°C	2.75			2.75			
				Full range	2.5			2.5			
V _{OL}	Low-level output voltage	V _{IC} = 0, I _{OL} = 100 μA		25°C	0.05			0.05			V
		V _{IC} = 0, I _{OL} = 250 μA		25°C	0.2			0.2			
				Full range	0.5			0.5			
A _{VD}	Large-signal differential voltage amplification	V _{IC} = 2.5 V, V _O = 1 V to 2 V	R _L = 10 kΩ‡	25°C	6	10		6	10		V/mV
			R _L = 1 MΩ‡	Full range	3			3			
				25°C	700			700			
r _{i(d)}	Differential input resistance			25°C	10 ¹²			10 ¹²			Ω
r _{i(c)}	Common-mode input resistance			25°C	10 ¹²			10 ¹²			Ω
c _{i(c)}	Common-mode input capacitance	f = 10 kHz		25°C	8			8			pF
z _o	Closed-loop output impedance	f = 100 kHz, A _V = 10		25°C	130			130			Ω
CMRR	Common-mode rejection ratio	V _{IC} = 0 to 2.5 V, V _O = 1.5 V, R _S = 50 Ω		25°C	70	83		70	83		dB
				Full range	70			70			
k _{SVR}	Supply-voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _{DD} = 2.7 V to 8 V, V _{IC} = V _{DD} /2, No load		25°C	80	95		80	95		dB
				Full range	80			80			
I _{DD}	Supply current	V _O = 1.5 V, No load		25°C	100	150		100	150		μA
				Full range	175			175			

† Full range is –40°C to 85°C.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.



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operating characteristics at specified free-air temperature, $V_{DD} = 3\text{ V}$

PARAMETER		TEST CONDITIONS		T _A [†]	TLV2422C, TLV2422I TLV2422AI			UNIT
					MIN	TYP	MAX	
SR	Slew rate at unity gain	V _O = 1.5 V to 3.5 V, R _L = 10 kΩ [‡] , C _L = 100 pF [‡]		25°C	0.01	0.02	V/μs	
				Full range	0.008			
V _n	Equivalent input noise voltage	f = 10 Hz		25°C	100		nV/√Hz	
		f = 1 kHz		25°C	23			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C	2.7		μV	
		f = 0.1 Hz to 10 Hz		25°C	4			
I _n	Equivalent input noise current			25°C	0.6		fA√Hz	
THD + N	Total harmonic distortion plus noise	V _O = 0.5 V to 2.5 V, f = 1 kHz, R _L = 10 kΩ [‡]	A _V = 1	25°C	0.25%			
			A _V = 10		1.8%			
Gain-bandwidth product		f = 10 kHz, C _L = 100 pF [‡]	R _L = 10 kΩ [‡] ,	25°C	46		kHz	
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 1 V, R _L = 10 kΩ [‡] ,	A _V = 1, C _L = 100 pF [‡]	25°C	8.3		kHz	
t _s	Settling time	A _V = −1, Step = 0.5 V to 2.5 V, R _L = 10 kΩ [‡] , C _L = 100 pF [‡]	To 0.1%	25°C	8.6		μs	
			To 0.01%		16			
φ _m	Phase margin at unity gain	R _L = 10 kΩ [‡] , C _L = 100 pF [‡]		25°C	62°			
Gain margin				25°C	11		dB	

† Full range for the C version is 0°C to 70°C. Full range for the I version is –40°C to 85°C.

‡ Referenced to 2.5 V

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electrical characteristics at specified free-air temperature, $V_{DD} = 3\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLV2422Q, TLV2422M			TLV2422AQ, TLV2422AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, V_{DD} \pm = \pm 1.5\text{ V}, R_S = 50\ \Omega$	25°C	300	2000		300	950		μV
		Full range		2500			1800		
α_{VIO} Temperature coefficient of input offset voltage		Full range		2			2		$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C		0.003			0.003		$\mu\text{V}/\text{mo}$
I_{IO} Input offset current		25°C		0.5	60		0.5	60	pA
		Full range			150			150	
I_{IB} Input bias current		25°C		1	60		1	60	pA
		Full range			300			300	
V_{ICR} Common-mode input voltage range		25°C	0 to 2.5	-0.25 to 2.75		0 to 2.5	-0.25 to 2.75		V
		Full range	0 to 2.2			0 to 2.2			
V_{OH} High-level output voltage	$I_{OH} = -100\ \mu\text{A}$	25°C		2.97			2.97		V
	$I_{OH} = -500\ \mu\text{A}$	25°C		2.75			2.75		
		Full range		2.5			2.5		
V_{OL} Low-level output voltage	$V_{IC} = 0, I_{OL} = 100\ \mu\text{A}$	25°C		0.05			0.05		V
	$V_{IC} = 0, I_{OL} = 250\ \mu\text{A}$	25°C		0.2			0.2		
		Full range			0.5			0.5	
A_{VD} Large-signal differential voltage amplification	$V_{IC} = 1.5\text{ V}, V_O = 1\text{ V to }2\text{ V}$	25°C	6	10		6	10		V/mV
		Full range		2			2		
		25°C		700			700		
$r_{i(d)}$ Differential input resistance		25°C		10^{12}			10^{12}		Ω
$r_{i(c)}$ Common-mode input resistance		25°C		10^{12}			10^{12}		Ω
$C_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$	25°C		8			8		pF
z_o Closed-loop output impedance	$f = 100\text{ kHz}, A_V = 10$	25°C		130			130		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR}\text{ min}, V_O = 1.5\text{ V}, R_S = 50\ \Omega$	25°C	70	83		70	83		dB
		Full range		70			70		
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 2.7\text{ V to }8\text{ V}, V_{IC} = V_{DD}/2, \text{ No load}$	25°C	80	95		80	95		dB
		Full range		80			80		
I_{DD} Supply current	$V_O = 1.5\text{ V}, \text{ No load}$	25°C		100	150		100	150	μA
		Full range			175			175	

† Full range is -40°C to 125°C for Q level part, -55°C to 125°C for M level part.

‡ Referenced to 1.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.



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operating characteristics at specified free-air temperature, $V_{DD} = 3\text{ V}$

PARAMETER		TEST CONDITIONS		T _A [†]	TLV2422Q, TLV2422M, TLV2422AQ, TLV2422AM			UNIT
					MIN	TYP	MAX	
SR	Slew rate at unity gain	V _O = 1.1 V to 1.9 V, R _L = 10 kΩ [‡] , C _L = 100 pF [‡]		25°C	0.01	0.02	V/μs	
				Full range	0.008			
V _n	Equivalent input noise voltage	f = 10 Hz		25°C	100		nV/√Hz	
		f = 1 kHz		25°C	23			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C	2.7		μV	
		f = 0.1 Hz to 10 Hz		25°C	4			
I _n	Equivalent input noise current			25°C	0.6		fA√Hz	
THD + N	Total harmonic distortion plus noise	V _O = 0.5 V to 2.5 V, f = 1 kHz, R _L = 10 kΩ [‡]	A _V = 1	25°C	0.25%			
			A _V = 10		1.8%			
Gain-bandwidth product		f = 10 kHz, C _L = 100 pF [‡]	R _L = 10 kΩ [‡] ,	25°C	46		kHz	
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 1 V, R _L = 10 kΩ [‡] ,	A _V = 1, C _L = 100 pF [‡]	25°C	8.3		kHz	
t _s	Settling time	A _V = −1, Step = 0.5 V to 2.5 V, R _L = 10 kΩ [‡] , C _L = 100 pF [‡]	To 0.1%	25°C	8.6		μs	
			To 0.01%		16			
φ _m	Phase margin at unity gain	R _L = 10 kΩ [‡] , C _L = 100 pF [‡]		25°C	62°			
Gain margin				25°C	11		dB	

† Full range is –40°C to 125°C for Q level part, –55°C to 125°C for M level part.

‡ Referenced to 1.5 V

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electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLV2422C			UNIT
			MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, V_{DD} \pm \pm 2.5\text{ V}, R_S = 50\ \Omega$	25°C		300	2000	μV
		Full range			2500	
αV_{IO} Temperature coefficient of input offset voltage		25°C to 70°C		2		$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C		0.003		$\mu\text{V}/\text{mo}$
I_{IO} Input offset current		25°C		0.5	60	pA
		Full range			150	
I_{IB} Input bias current		25°C		1	60	pA
		Full range			150	
V_{ICR} Common-mode input voltage range	$ V_{IO} \leq 5\text{ mV}, R_S = 50\ \Omega$	25°C	0 to 4.5	-0.25 to 4.75		V
		Full range	0 to 4.2			
V_{OH} High-level output voltage	$I_{OH} = -100\ \mu\text{A}$	25°C		4.97		V
	$I_{OH} = -1\text{ mA}$	25°C		4.5	4.75	
		Full range		4.25		
V_{OL} Low-level output voltage	$V_{IC} = 2.5\text{ V}, I_{OL} = 100\ \mu\text{A}$	25°C		0.04		V
	$V_{IC} = 2.5\text{ V}, I_{OL} = 500\ \mu\text{A}$	25°C		0.15		
		Full range			0.5	
A_{VD} Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}, V_O = 1\text{ V to }4\text{ V}$	25°C	8	12		V/mV
		Full range		5		
		25°C		1000		
$r_{i(d)}$ Differential input resistance		25°C		10^{12}		Ω
$r_{i(c)}$ Common-mode input resistance		25°C		10^{12}		Ω
$C_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$	25°C		8		pF
z_O Closed-loop output impedance	$f = 100\text{ kHz}, A_V = 10$	25°C		130		Ω
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to }4.5\text{ V}, V_O = 2.5\text{ V}, R_S = 50\ \Omega$	25°C	70	90		dB
		Full range		70		
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 4.4\text{ V to }8\text{ V}, V_{IC} = V_{DD}/2, \text{ No load}$	25°C	80	95		dB
		Full range		80		
I_{DD} Supply current	$V_O = 2.5\text{ V}, \text{ No load}$	25°C		100	150	μA
		Full range			175	

† Full range is 0°C to 70°C.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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PARAMETER		TEST CONDITIONS		T _A [†]	TLV2422I			TLV2422AI			UNIT	
					MIN	TYP	MAX	MIN	TYP	MAX		
V _{IO}	Input offset voltage	V _{IC} = 0, V _O = 0, V _{DD} ± = ±2.5 V, R _S = 50 Ω		25°C	300		2000	300		950	μV	
Full range				2500		1500						
α _{VIO}	Temperature coefficient of input offset voltage			25°C to 70°C	2		2		μV/°C			
	Input offset voltage long-term drift (see Note 4)			25°C	0.003		0.003		μV/mo			
I _{IO}	Input offset current			25°C	0.5		60	0.5		60	pA	
				Full range		150		150				
I _{IB}	Input bias current			25°C	1		60	1		60	pA	
				Full range		150		150				
V _{ICR}	Common-mode input voltage range	V _{IO} ≤ 5 mV, R _S = 50 Ω		25°C	0 to 4.5		−0.25 to 4.75		0 to 4.5		V	
				Full range	0 to 4.2		0 to 4.2					
V _{OH}	High-level output voltage	I _{OH} = −100 μA		25°C	4.97		4.97		V			
		I _{OH} = −1 mA		25°C	4.5		4.75	4.5			4.75	
				Full range	4.25		4.25					
V _{OL}	Low-level output voltage	V _{IC} = 2.5 V, I _{OL} = 100 μA		25°C	0.04		0.04		V			
		V _{IC} = 2.5 V, I _{OL} = 500 μA		25°C	0.15		0.15					
				Full range		0.5		0.5				
A _{VD}	Large-signal differential voltage amplification	V _{IC} = 2.5 V, V _O = 1 V to 4 V	R _L = 10 kΩ‡	25°C	8		12	8		12	V/mV	
			R _L = 1 MΩ‡	Full range	5		5					
				25°C	1000		1000					
r _{i(d)}	Differential input resistance			25°C	10 ¹²		10 ¹²		Ω			
r _{i(c)}	Common-mode input resistance			25°C	10 ¹²		10 ¹²		Ω			
c _{i(c)}	Common-mode input capacitance	f = 10 kHz		25°C	8		8		pF			
z _o	Closed-loop output impedance	f = 100 kHz, A _V = 10		25°C	130		130		Ω			
CMRR	Common-mode rejection ratio	V _{IC} = 0 to 4.5 V, V _O = 2.5 V, R _S = 50 Ω		25°C	70		90	70		90	dB	
				Full range		70		70				
k _{SVR}	Supply-voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _{DD} = 4.4 V to 8 V, V _{IC} = V _{DD} /2, No load		25°C	80		95	80		95	dB	
				Full range		80		80				
I _{DD}	Supply current	V _O = 2.5 V, No load		25°C	100		150	100		150	μA	
				Full range		175		175				

† Full range is -40°C to 85°C .

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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PARAMETER		TEST CONDITIONS		T _A [†]	TLV2422C, TLV2422I TLV2422AI			UNIT
					MIN	TYP	MAX	
SR	Slew rate at unity gain	V _O = 1.5 V to 3.5 V, R _L = 10 kΩ [‡] , C _L = 100 pF [‡]		25°C	0.01	0.02	V/μs	
				Full range	0.008			
V _n	Equivalent input noise voltage	f = 10 Hz		25°C	100		nV/√Hz	
		f = 1 kHz		25°C	18			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C	1.9		μV	
		f = 0.1 Hz to 10 Hz		25°C	2.8			
I _n	Equivalent input noise current			25°C	0.6		fA/√Hz	
THD + N	Total harmonic distortion plus noise	V _O = 1.5 V to 3.5 V, f = 1 kHz, R _L = 10 kΩ [‡]	A _V = 1	25°C	0.24%			
			A _V = 10		1.7%			
Gain-bandwidth product		f = 10 kHz, C _L = 100 pF [‡]	R _L = 10 kΩ [‡] ,	25°C	52		kHz	
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 2 V, R _L = 10 kΩ [‡] ,	A _V = 1, C _L = 100 pF [‡]	25°C	5.3		kHz	
t _s	Settling time	A _V = −1, Step = 1.5 V to 3.5 V, R _L = 10 kΩ [‡] , C _L = 100 pF [‡]	To 0.1%	25°C	8.5		μs	
			To 0.01%		15.5			
φ _m	Phase margin at unity gain	R _L = 10 kΩ [‡] , C _L = 100 pF [‡]		25°C	66°			
Gain margin				25°C	11		dB	

† Full range for the C version is 0°C to 70°C. Full range for the I version is –40°C to 85°C.

‡ Referenced to 2.5 V



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PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLV2422Q, TLV2422M			TLV2422AQ, TLV2422AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, V_{DD} \pm = \pm 2.5\text{ V}, R_S = 50\ \Omega$	25°C	300	2000		300	950		μV
		Full range		2500			1800		
α_{VIO} Temperature coefficient of input offset voltage		Full range	2			2			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C	0.003			0.003			$\mu\text{V}/\text{mo}$
I_{IO} Input offset current		25°C	0.5	60		0.5	60		pA
		Full range		150			150		
I_{IB} Input bias current		25°C	1	60		1	60		pA
		Full range		300			300		
V_{ICR} Common-mode input voltage range		25°C	0 to 4.5	-0.25 to 4.75		0 to 4.5	-0.25 to 4.75		V
		Full range	0 to 4.2			0 to 4.2			
V_{OH} High-level output voltage	$I_{OH} = -100\ \mu\text{A}$	25°C	4.97			4.97			V
	$I_{OH} = -1\text{ mA}$	25°C	4.75			4.75			
		Full range	4.5			4.5			
V_{OL} Low-level output voltage	$V_{IC} = 2.5\text{ V}, I_{OL} = 100\ \mu\text{A}$	25°C	0.04			0.04			V
	$V_{IC} = 2.5\text{ V}, I_{OL} = 500\ \mu\text{A}$	25°C	0.15			0.15			
		Full range		0.5			0.5		
A_{VD} Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}, V_O = 1\text{ V to }4\text{ V}$	$R_L = 10\text{ k}\Omega^\ddagger$	25°C	8	12	8	12		V/mV
			Full range	3		3			
		$R_L = 1\text{ M}\Omega^\ddagger$	25°C	1000		1000			
$r_{i(d)}$ Differential input resistance		25°C	10 ¹²			10 ¹²			Ω
$r_{i(c)}$ Common-mode input resistance		25°C	10 ¹²			10 ¹²			Ω
$c_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$	25°C	8			8			pF
z_o Closed-loop output impedance	$f = 100\text{ kHz}, A_V = 10$	25°C	130			130			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR}\text{ min}, V_O = 2.5\text{ V}, R_S = 50\ \Omega$	25°C	70	90		70	90		dB
		Full range	70			70			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 4.4\text{ V to }8\text{ V}, V_{IC} = V_{DD}/2, \text{ No load}$	25°C	80	95		80	95		dB
		Full range	80			80			
I_{DD} Supply current	$V_O = 2.5\text{ V}, \text{ No load}$	25°C	100	150		100	150		μA
		Full range		175			175		

† Full range is -40°C to 125°C for Q level part, -55°C to 125°C for M level part.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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PARAMETER		TEST CONDITIONS		T _A [†]	TLV2422Q, TLV2422M, TLV2422AQ, TLV2422AM			UNIT
					MIN	TYP	MAX	
SR	Slew rate at unity gain	V _O = 1.5 V to 3.5 V, R _L = 10 kΩ [‡] , C _L = 100 pF [‡]		25°C	0.01	0.02	V/μs	
				Full range	0.008			
V _n	Equivalent input noise voltage	f = 10 Hz		25°C	100		nV/√Hz	
		f = 1 kHz		25°C	18			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C	1.9		μV	
		f = 0.1 Hz to 10 Hz		25°C	2.8			
I _n	Equivalent input noise current			25°C	0.6		fA/√Hz	
THD + N	Total harmonic distortion plus noise	V _O = 1.5 V to 3.5 V, f = 1 kHz, R _L = 10 kΩ [‡]	A _V = 1	25°C	0.24%			
			A _V = 10		1.7%			
Gain-bandwidth product		f = 10 kHz, R _L = 10 kΩ [‡] , C _L = 100 pF [‡]		25°C	52		kHz	
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 2 V, R _L = 10 kΩ [‡] , A _V = 1, C _L = 100 pF [‡]		25°C	5.3		kHz	
t _s	Settling time	A _V = −1, Step = 1.5 V to 3.5 V, R _L = 10 kΩ [‡] , C _L = 100 pF [‡]	To 0.1%	25°C	8.5		μs	
			To 0.01%		15.5			
φ _m	Phase margin at unity gain	R _L = 10 kΩ [‡] , C _L = 100 pF [‡]		25°C	66°			
Gain margin				25°C	11		dB	

† Full range is -40°C to 125°C for Q level part, -55°C to 125°C for M level part.

‡ Referenced to 2.5 V

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	Gain margin	vs Load capacitance	49
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DISTRIBUTION OF TLV2422
INPUT OFFSET VOLTAGE

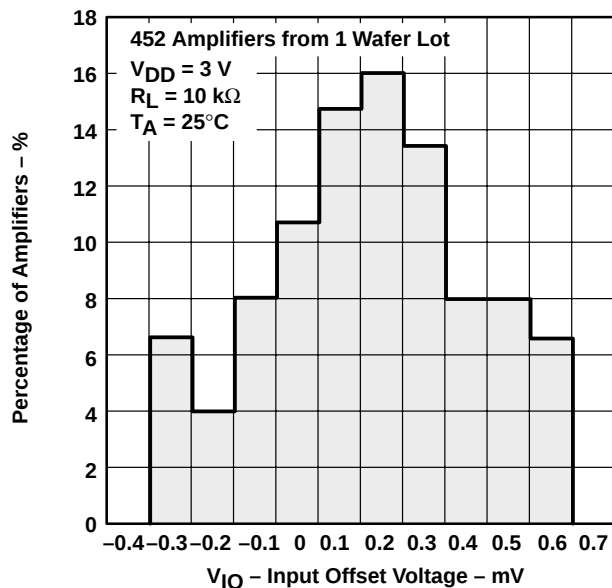


Figure 2

DISTRIBUTION OF TLV2422
INPUT OFFSET VOLTAGE

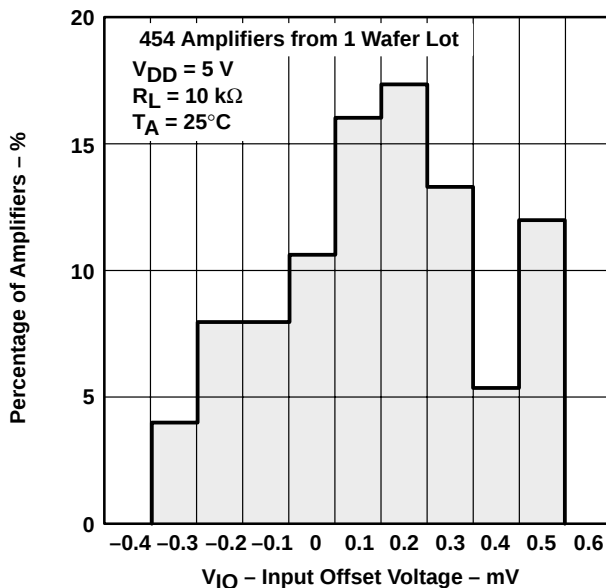


Figure 3

INPUT OFFSET VOLTAGE
VS
COMMON-MODE INPUT VOLTAGE

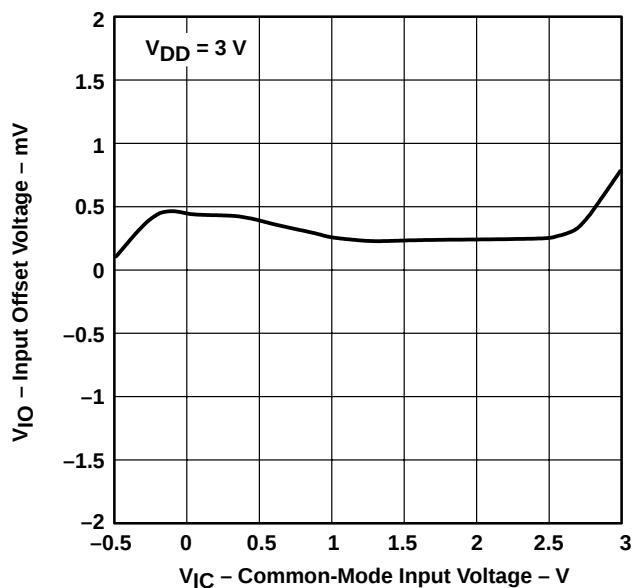


Figure 4

INPUT OFFSET VOLTAGE
VS
COMMON-MODE INPUT VOLTAGE

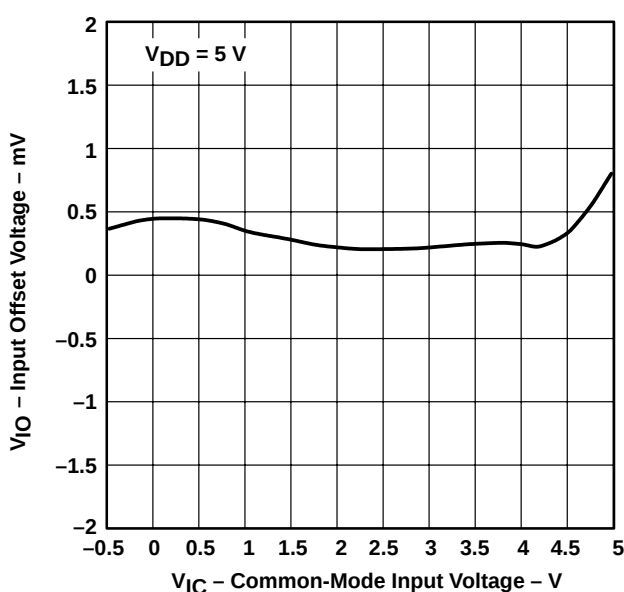


Figure 5

TYPICAL CHARACTERISTICS

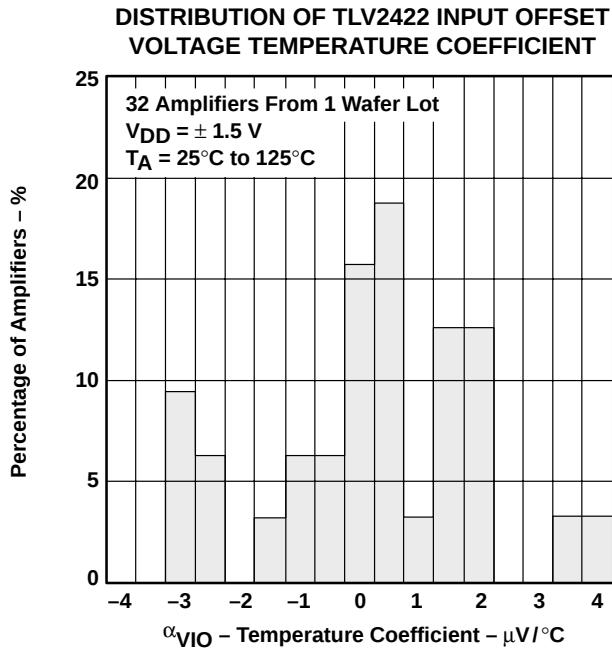


Figure 6

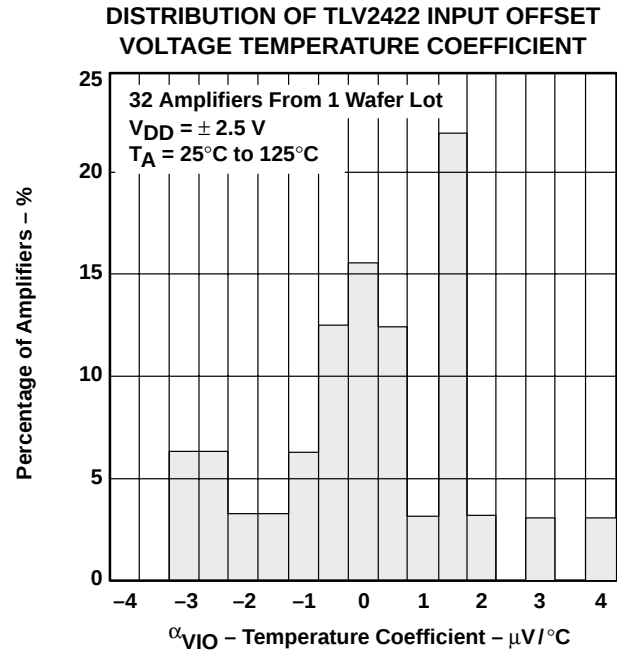


Figure 7

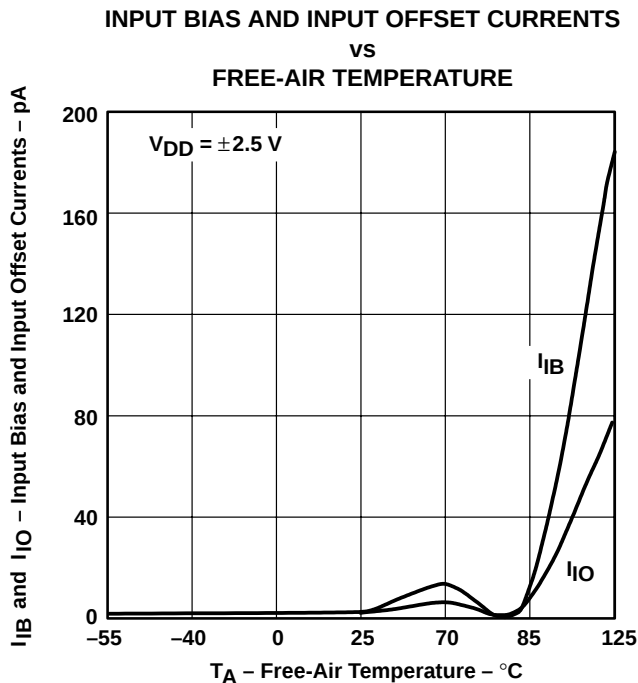


Figure 8

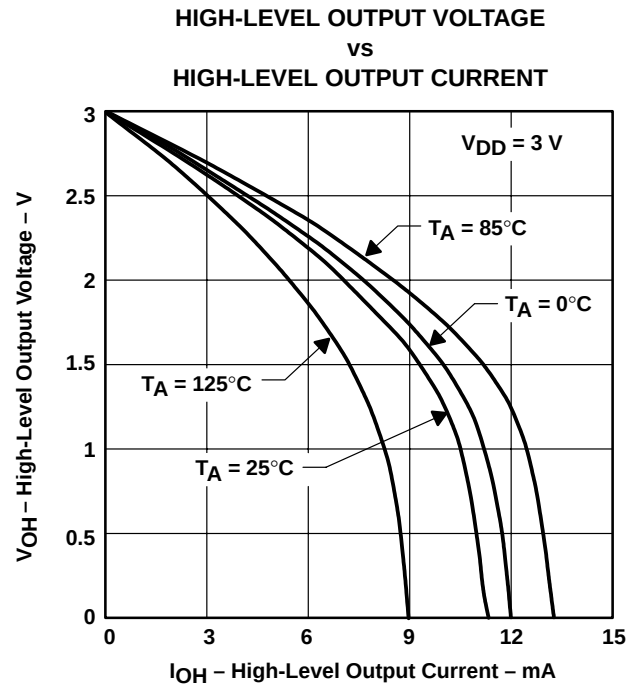


Figure 9

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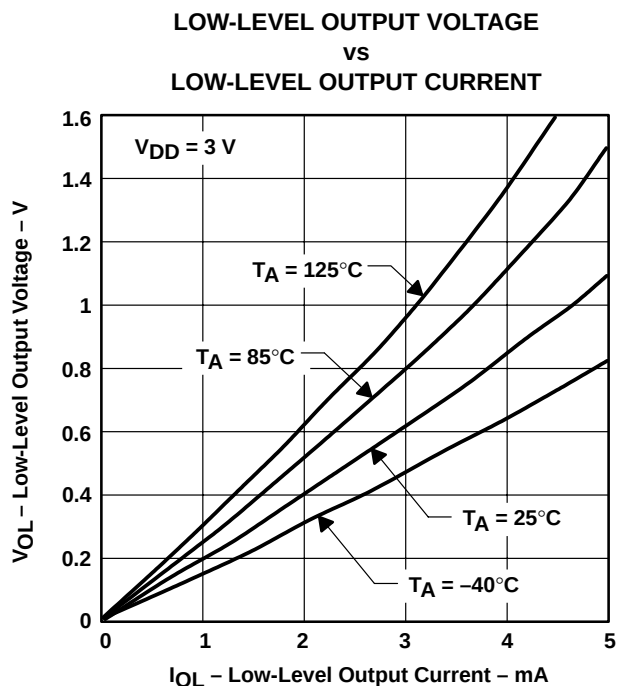


Figure 10

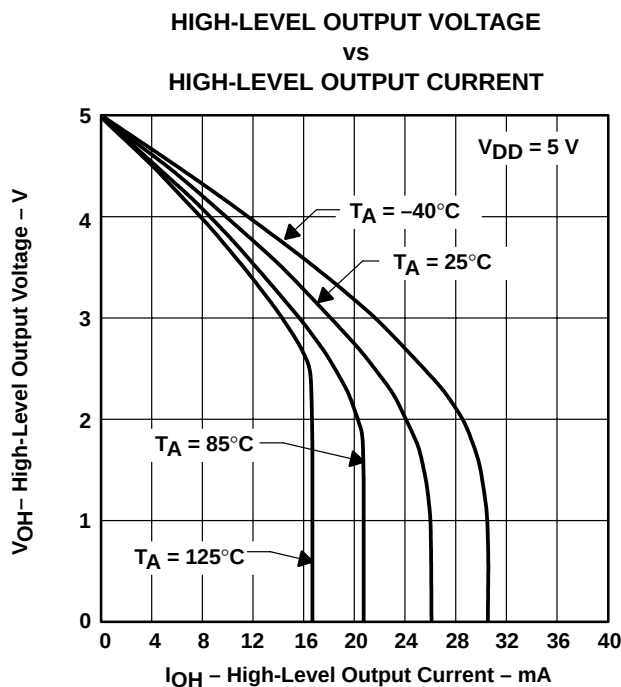


Figure 11

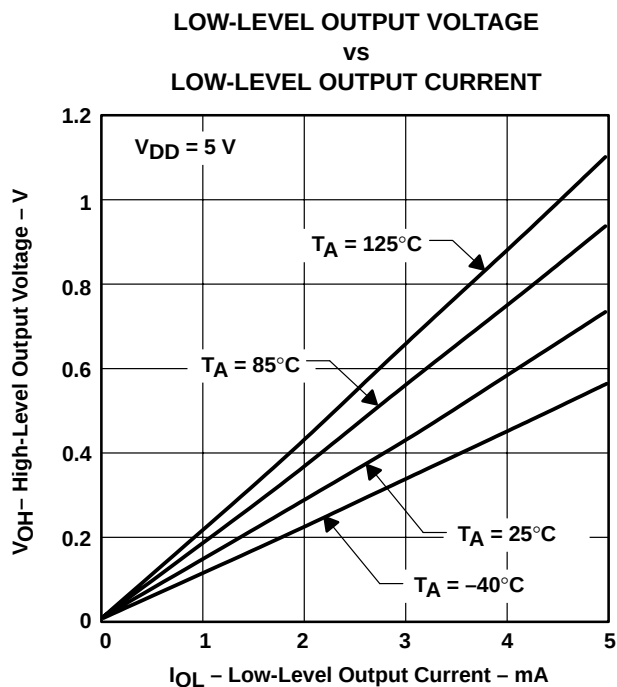


Figure 12

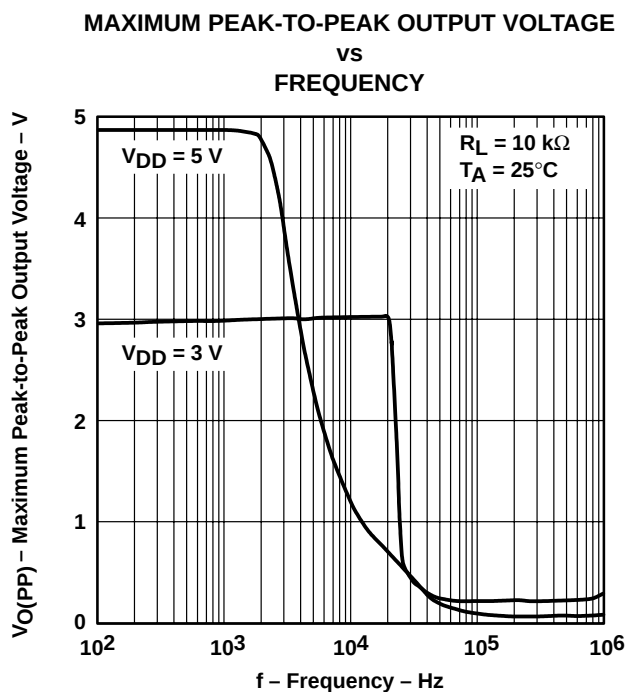
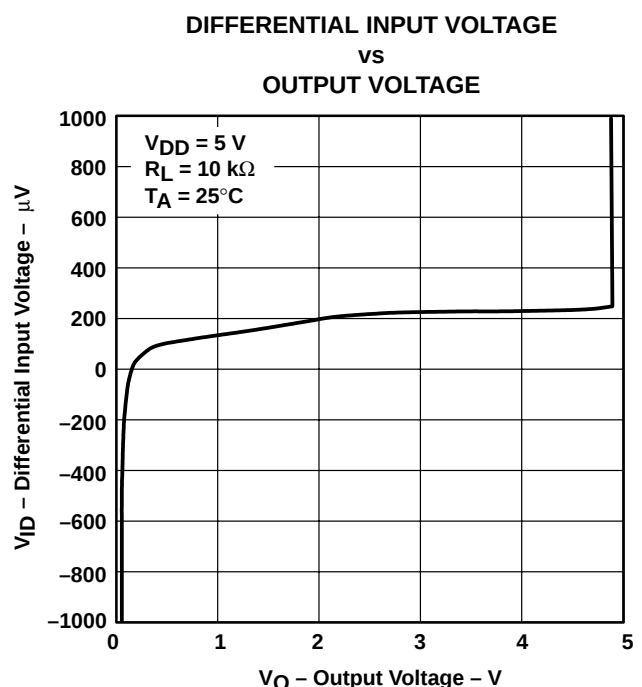
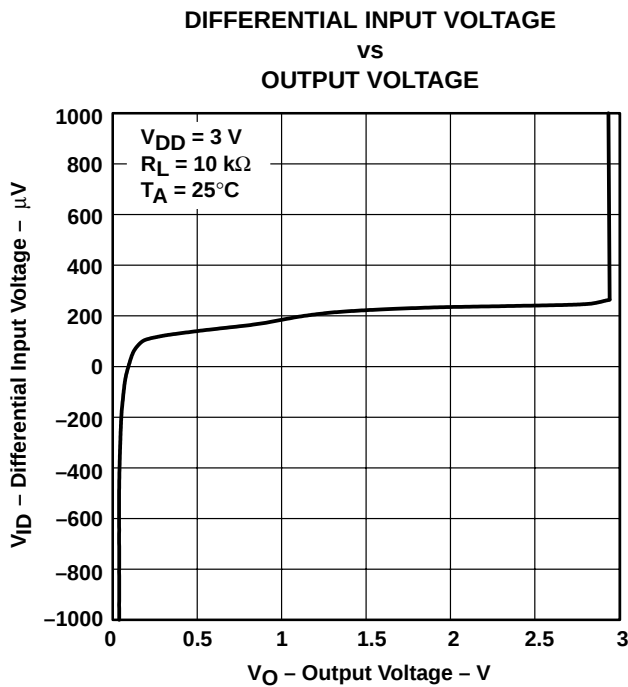
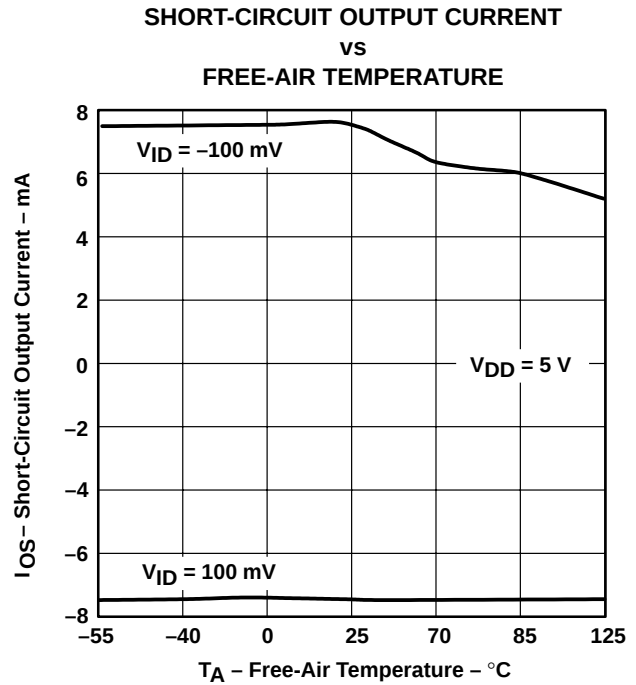
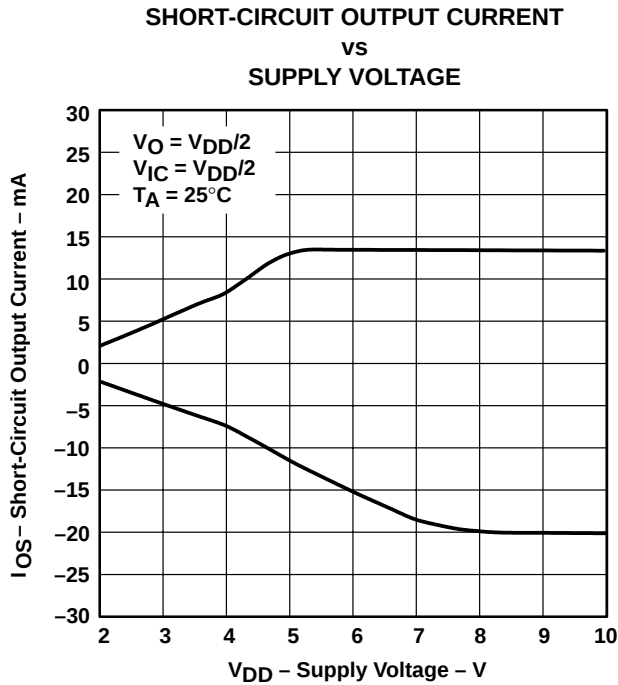


Figure 13

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

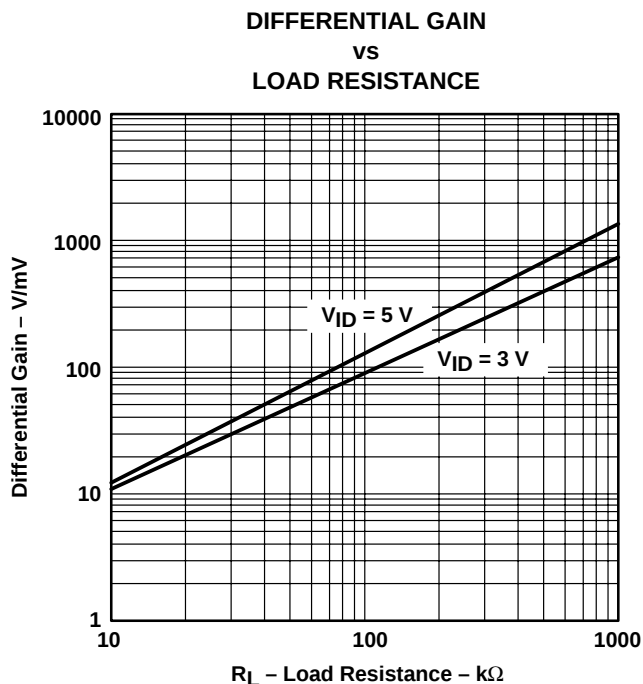


Figure 18

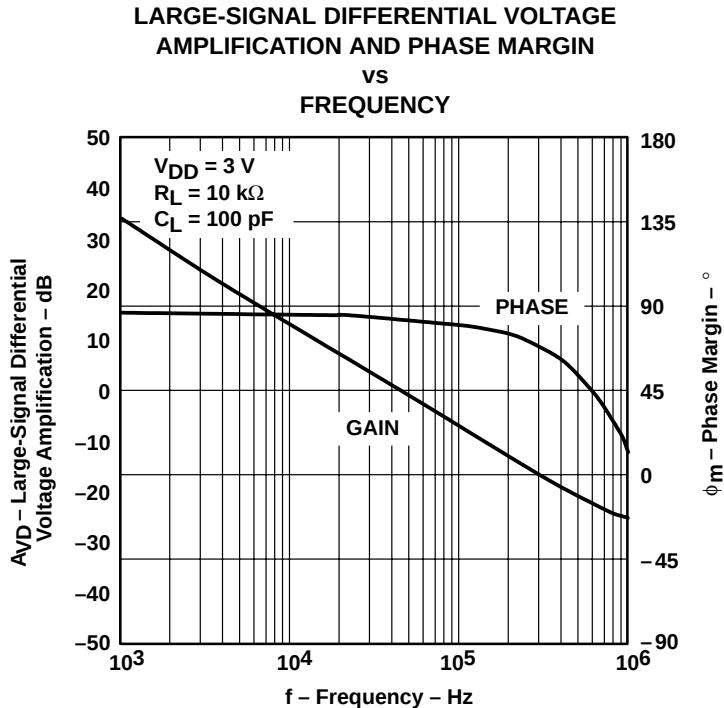


Figure 19

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN

VS
FREQUENCY

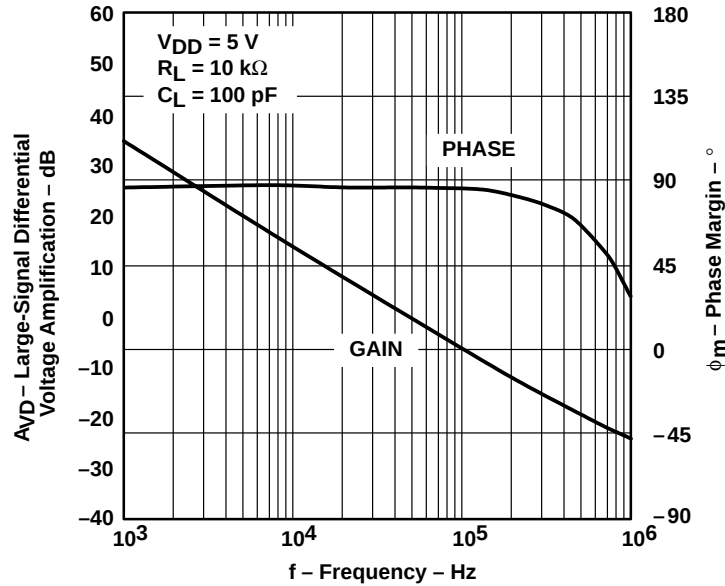


Figure 20

DIFFERENTIAL VOLTAGE AMPLIFICATION VS FREE-AIR TEMPERATURE

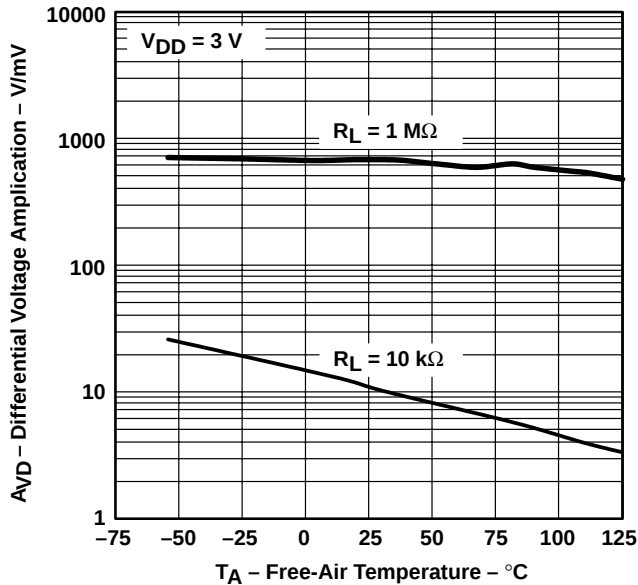


Figure 21

DIFFERENTIAL VOLTAGE AMPLIFICATION VS FREE-AIR TEMPERATURE

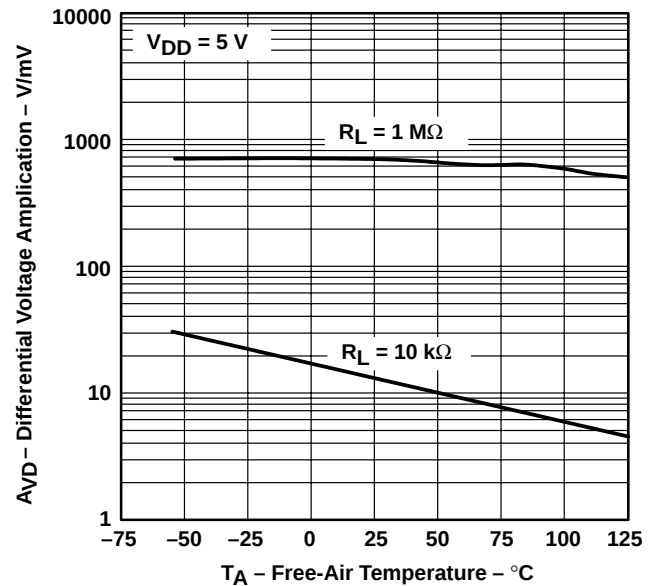


Figure 22

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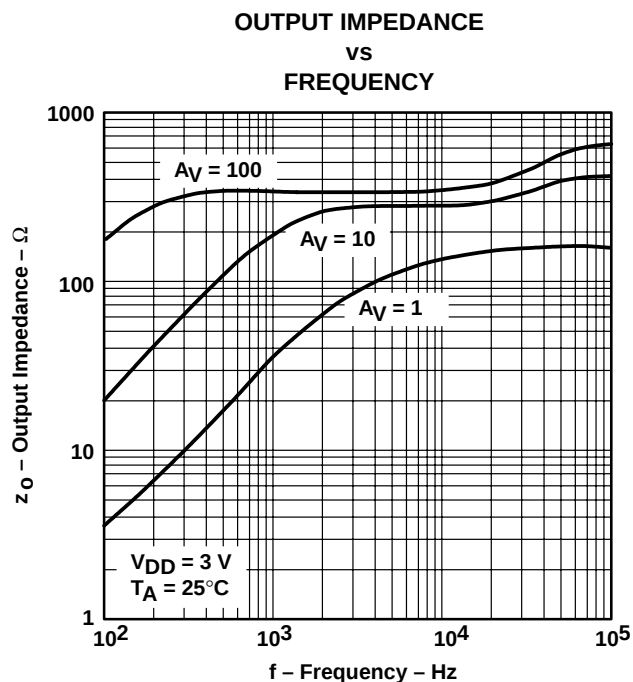


Figure 23

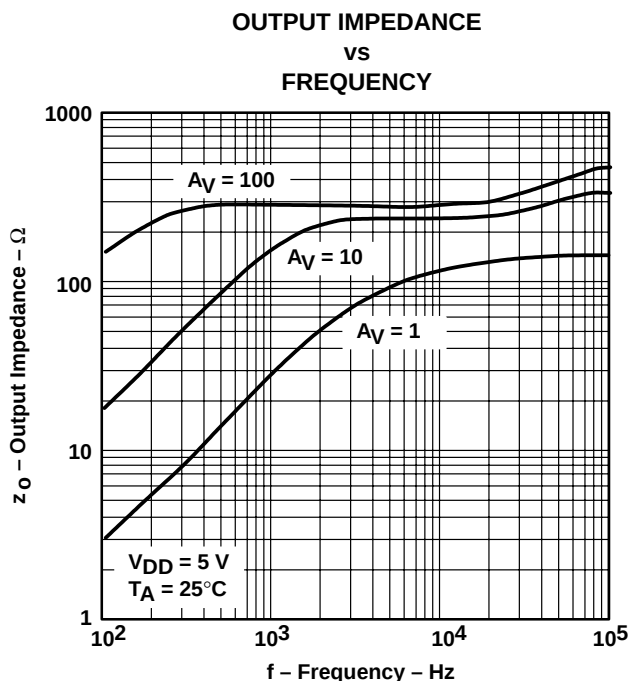


Figure 24

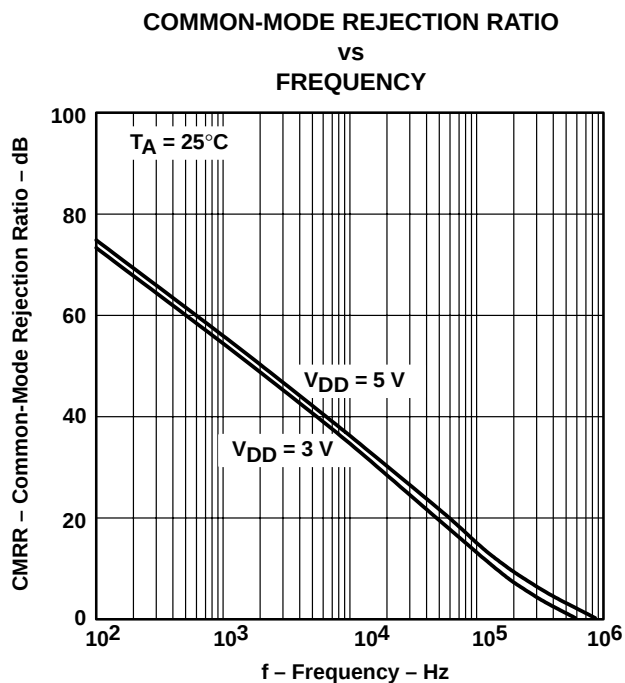


Figure 25

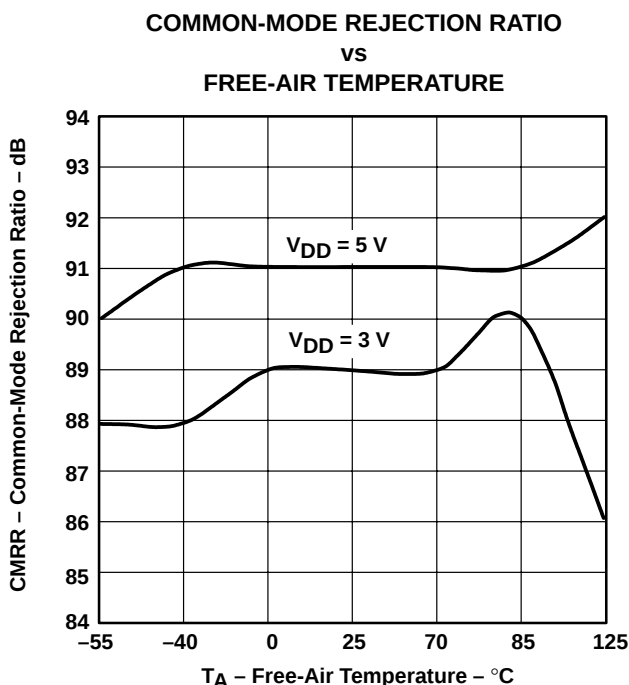


Figure 26

TYPICAL CHARACTERISTICS

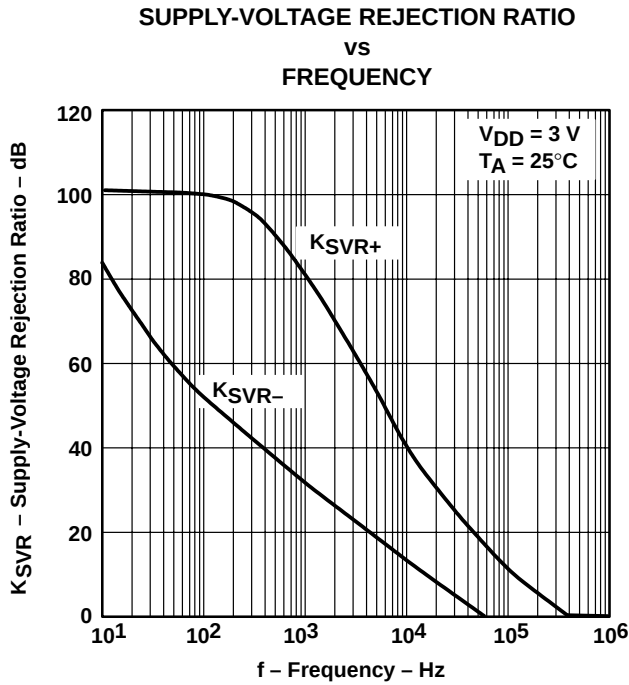


Figure 27

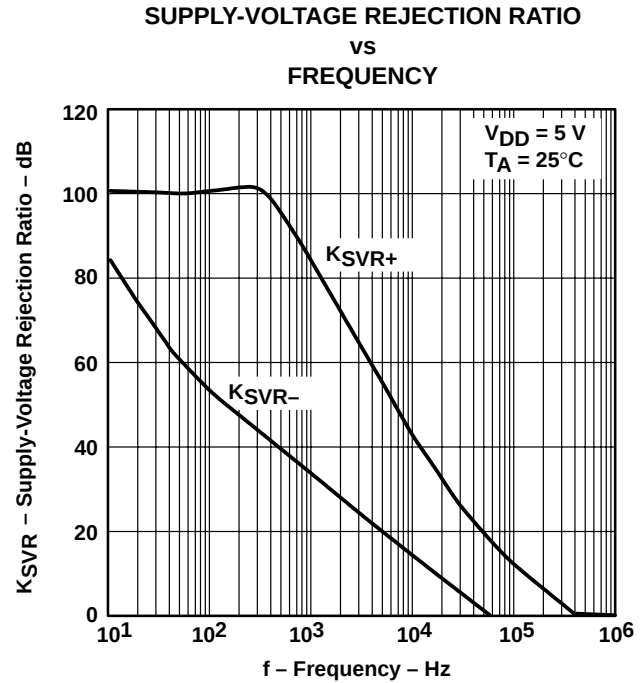


Figure 28

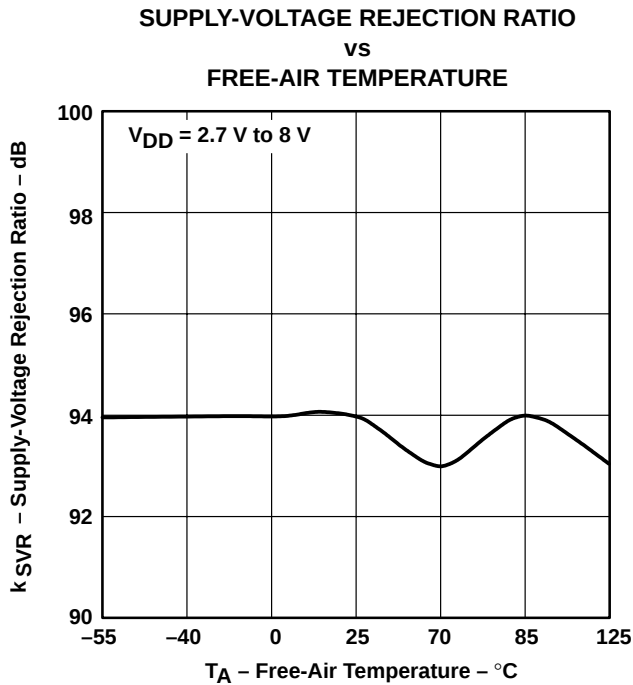


Figure 29

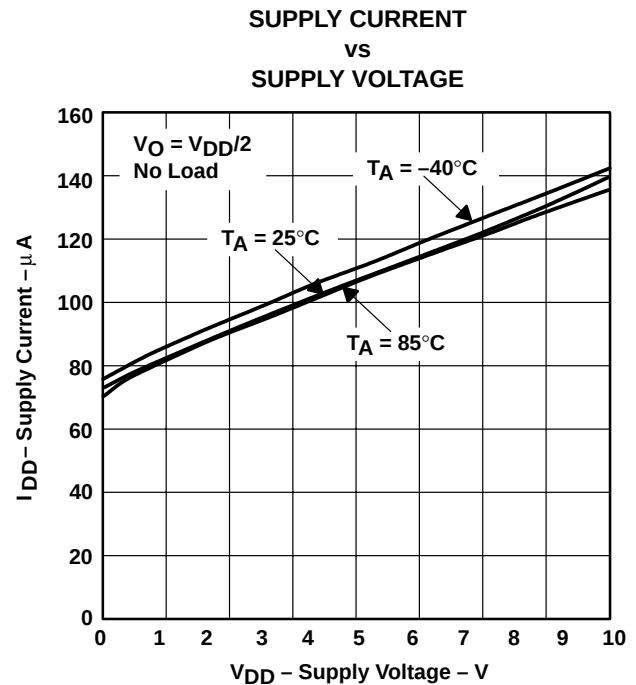


Figure 30

TLV2422, TLV2422A
Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT
WIDE-INPUT-VOLTAGE MICROPOWER DUAL OPERATIONAL AMPLIFIERS

SLOS199C – SEPTEMBER 1997 – REVISED APRIL 2001

TYPICAL CHARACTERISTICS

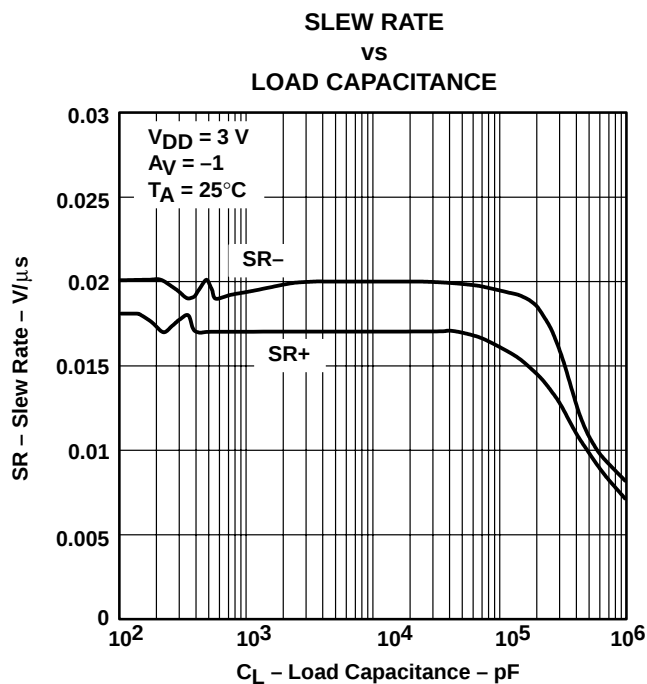


Figure 31

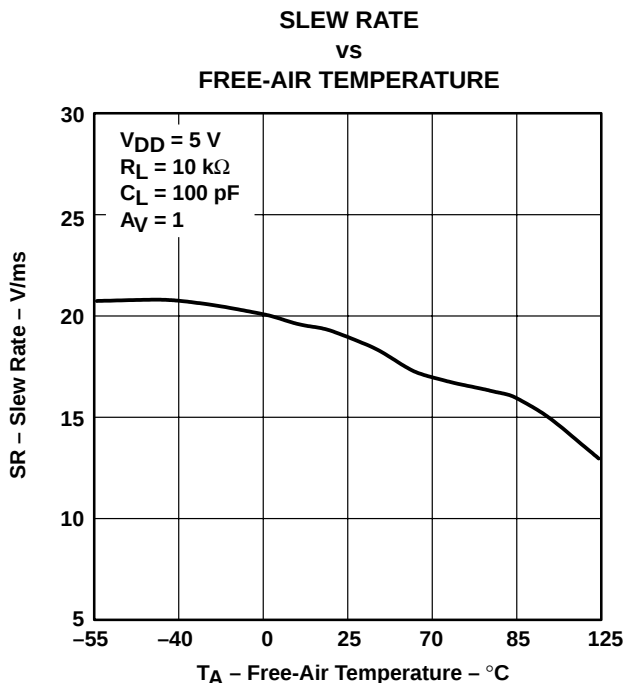


Figure 32

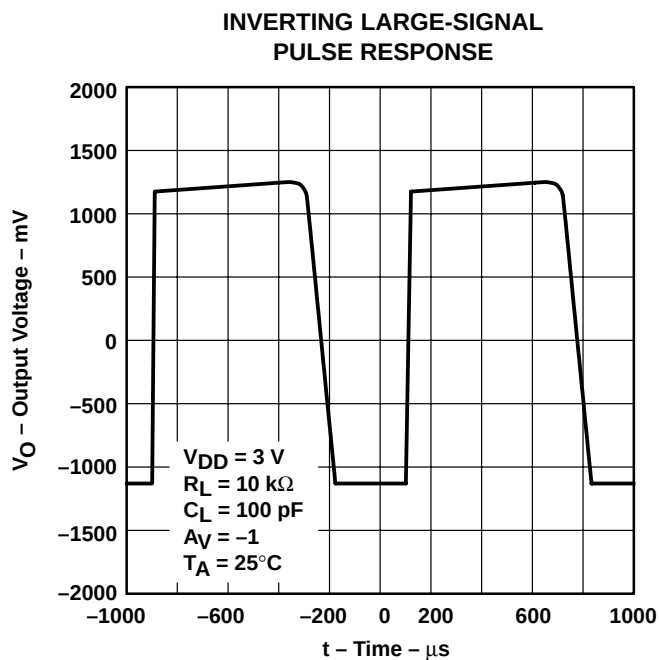


Figure 33

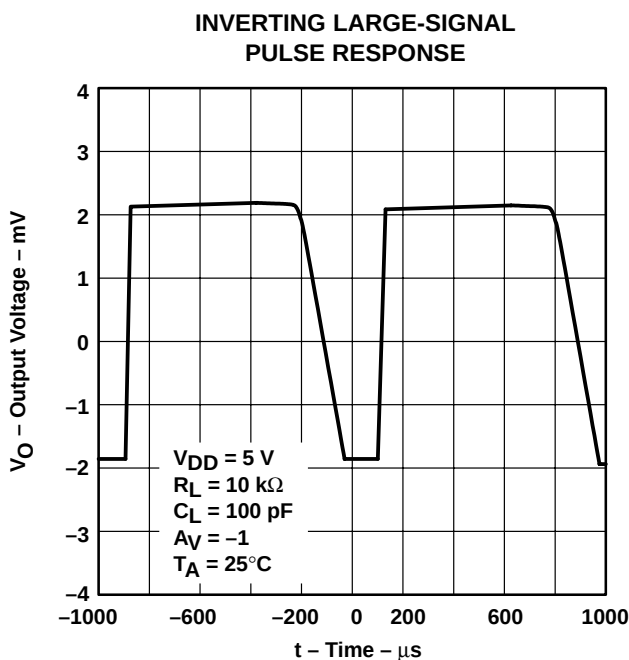


Figure 34

TYPICAL CHARACTERISTICS

**VOLTAGE-FOLLOWER LARGE-SIGNAL
PULSE RESPONSE**

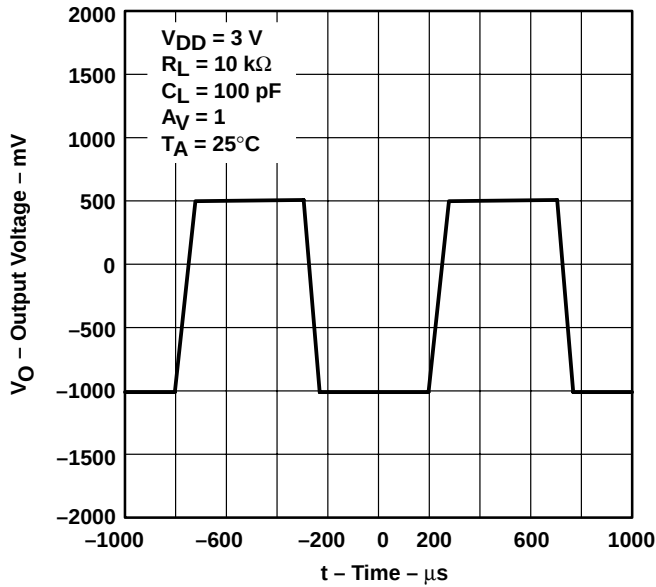


Figure 35

**VOLTAGE-FOLLOWER LARGE-SIGNAL
PULSE RESPONSE**

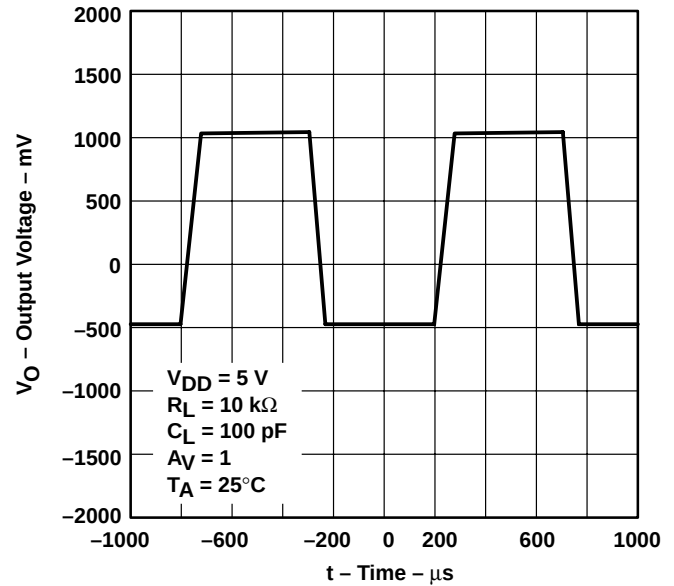


Figure 36

**INVERTING SMALL-SIGNAL
PULSE RESPONSE**

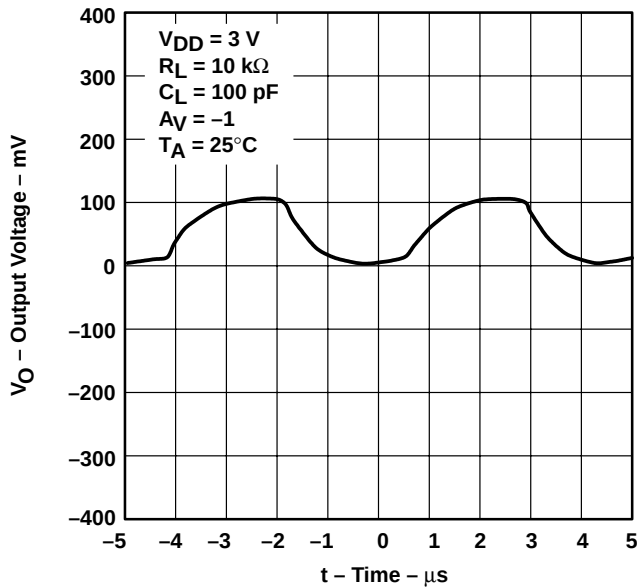


Figure 37

**INVERTING SMALL-SIGNAL
PULSE RESPONSE**

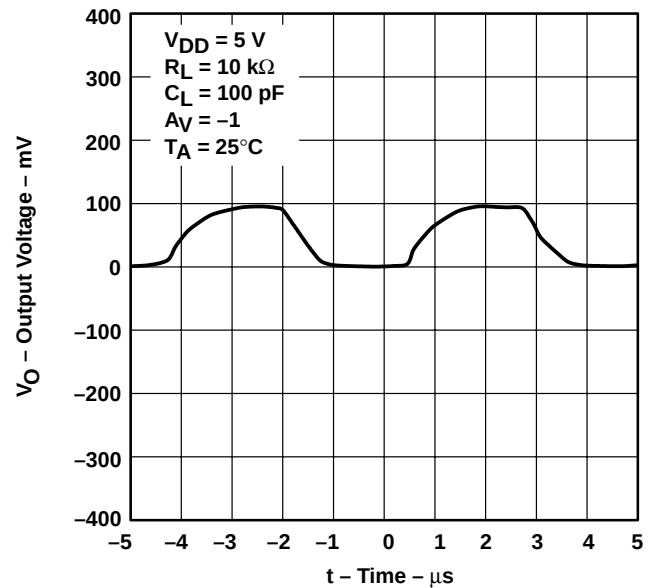


Figure 38

TLV2422, TLV2422A

Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT

WIDE-INPUT-VOLTAGE MICROPOWER DUAL OPERATIONAL AMPLIFIERS

SLOS199C – SEPTEMBER 1997 – REVISED APRIL 2001

TYPICAL CHARACTERISTICS

VOLTAGE-FOLLOWER SMALL-SIGNAL
PULSE RESPONSE

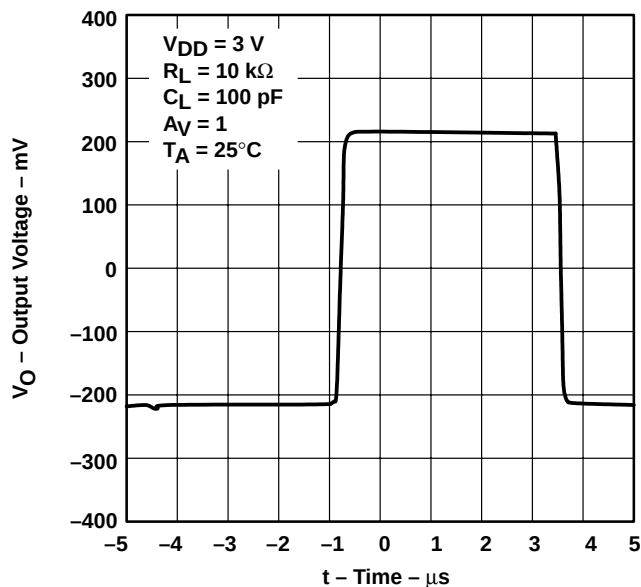


Figure 39

VOLTAGE-FOLLOWER SMALL-SIGNAL
PULSE RESPONSE

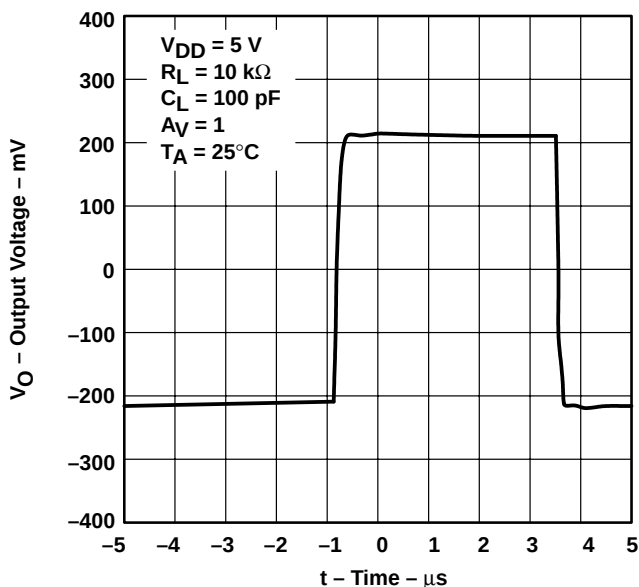


Figure 40

EQUIVALENT INPUT NOISE VOLTAGE
VS
FREQUENCY

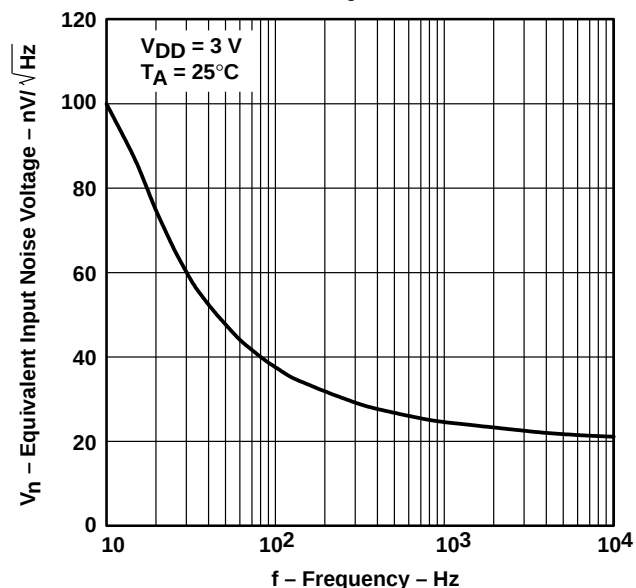


Figure 41

EQUIVALENT INPUT NOISE VOLTAGE
VS
FREQUENCY

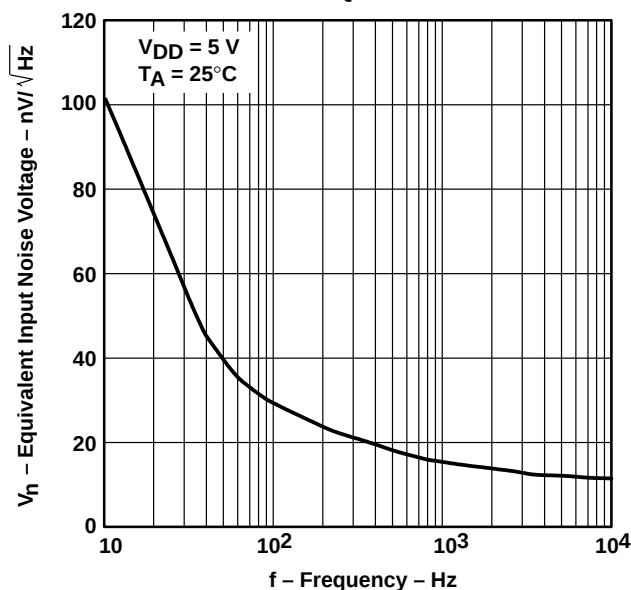


Figure 42

TYPICAL CHARACTERISTICS

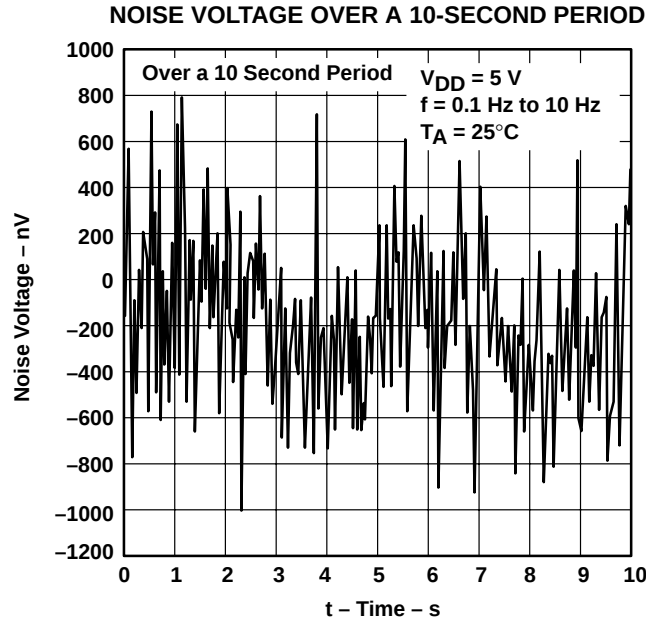


Figure 43

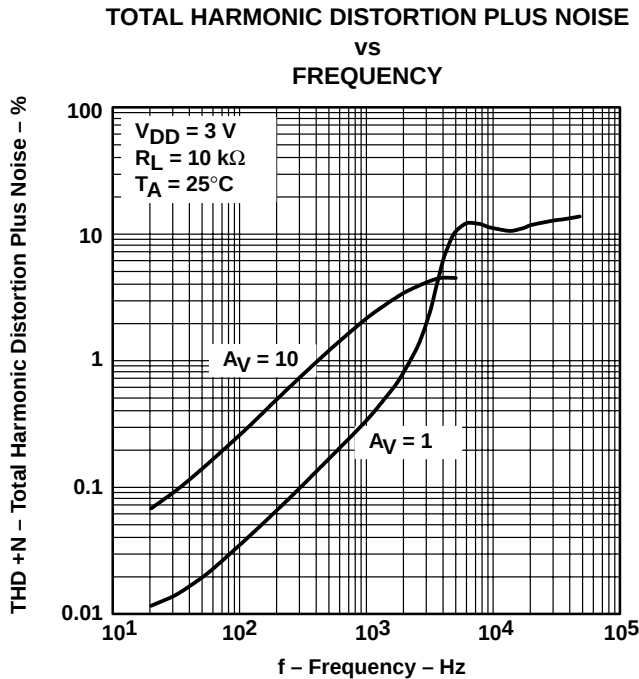


Figure 44

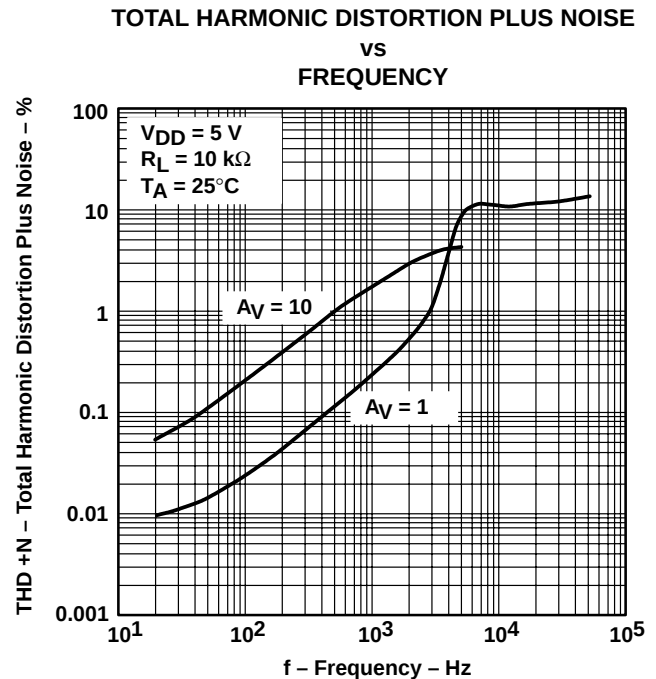


Figure 45

TLV2422, TLV2422A

Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT

WIDE-INPUT-VOLTAGE MICROPOWER DUAL OPERATIONAL AMPLIFIERS

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TYPICAL CHARACTERISTICS

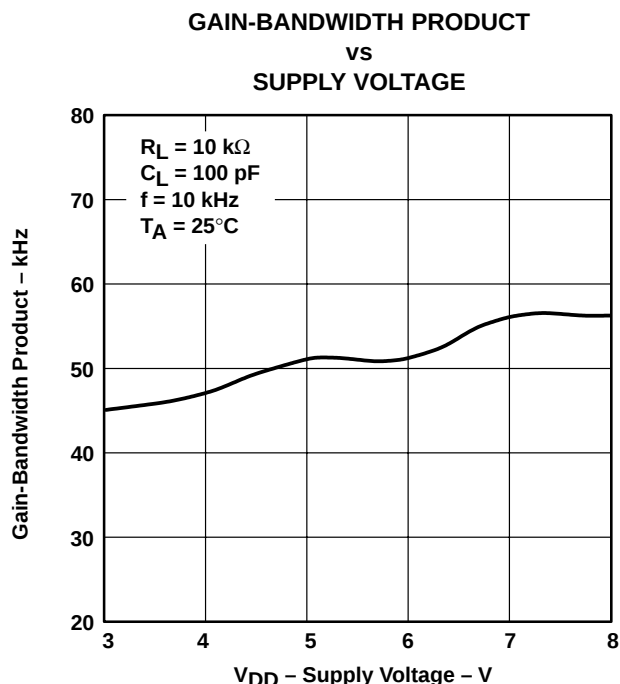


Figure 46

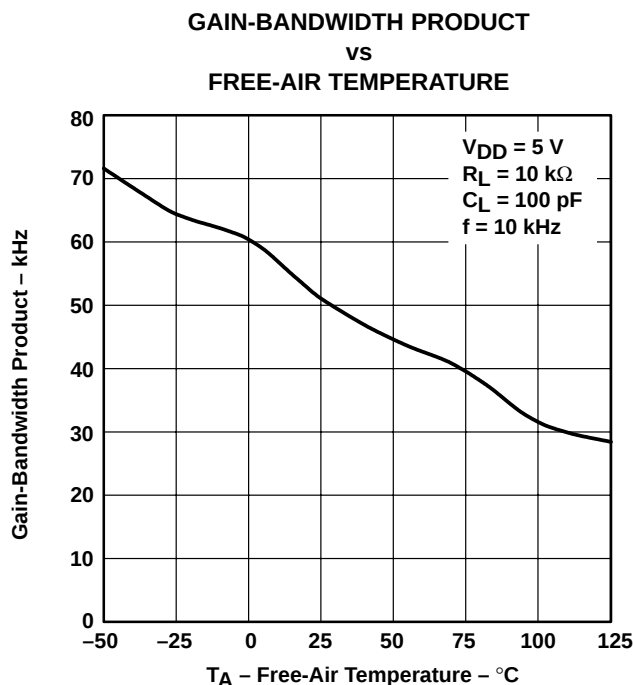


Figure 47

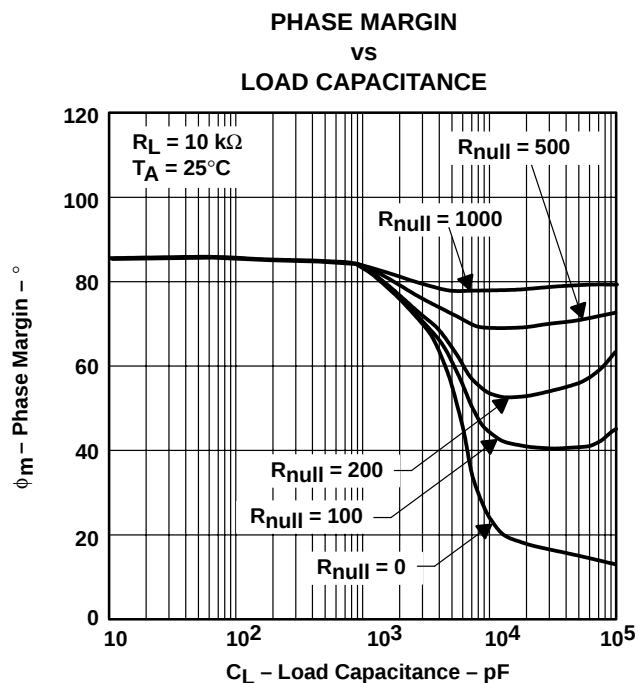


Figure 48

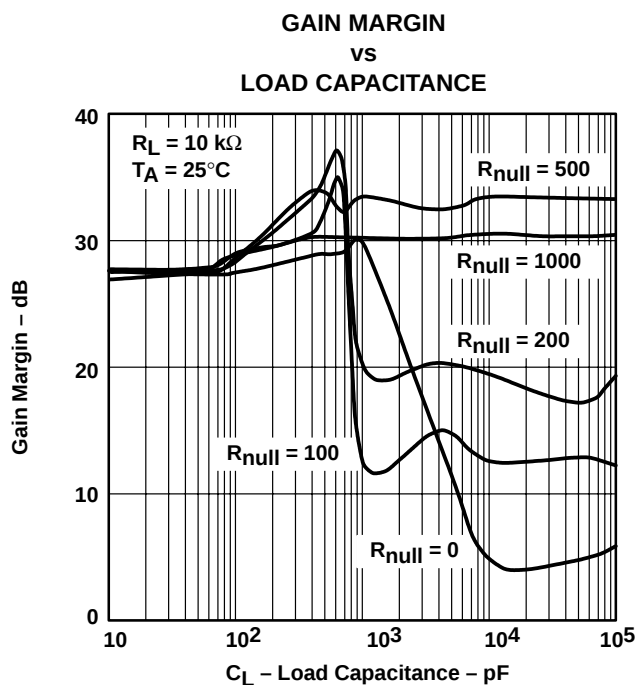


Figure 49

TYPICAL CHARACTERISTICS

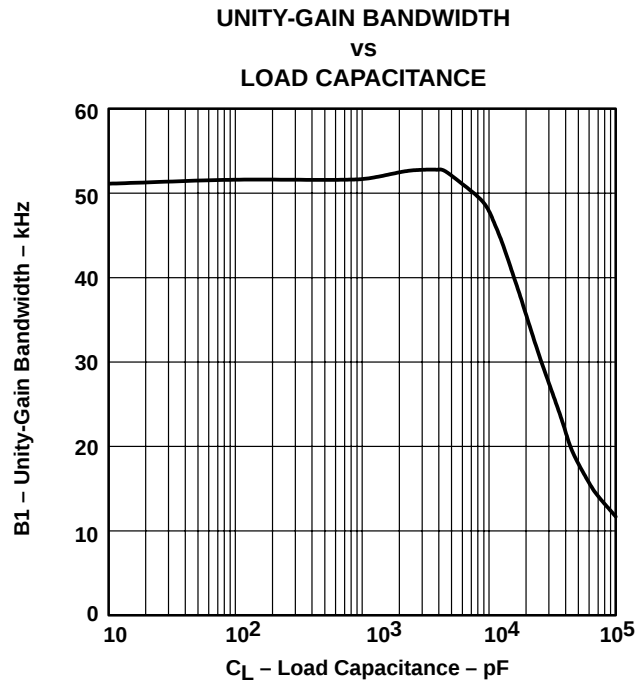


Figure 50

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9751401QHA	ACTIVE	CFP	U	10	1	TBD	A42	N / A for Pkg Type	-55 to 125	9751401QHA TLV2422M	Samples
5962-9751402QHA	ACTIVE	CFP	U	10	1	TBD	A42	N / A for Pkg Type	-55 to 125	9751402QHA TLV2422AM	Samples
TLV2422AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2422AI	Samples
TLV2422AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2422AI	Samples
TLV2422AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2422AI	Samples
TLV2422AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2422AI	Samples
TLV2422AIPWLE	OBSOLETE	TSSOP	PW	8		TBD	Call TI	Call TI	-40 to 85		
TLV2422AIPWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2422AI	Samples
TLV2422AIPWRG4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2422AI	Samples
TLV2422AMUB	ACTIVE	CFP	U	10	1	TBD	A42	N / A for Pkg Type	-55 to 125	9751402QHA TLV2422AM	Samples
TLV2422AQD	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 125	V2422A	
TLV2422AQDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2422A	Samples
TLV2422AQDR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 125	V2422A	
TLV2422AQDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2422A	Samples
TLV2422CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2422C	Samples
TLV2422CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2422C	Samples
TLV2422CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2422C	Samples
TLV2422CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2422C	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2422CPWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TV2422	Samples
TLV2422CPWRG4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TV2422	Samples
TLV2422ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2422I	Samples
TLV2422IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2422I	Samples
TLV2422IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2422I	Samples
TLV2422IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2422I	Samples
TLV2422IPW	OBSOLETE	TSSOP	PW	8		TBD	Call TI	Call TI	-40 to 85		
TLV2422IPWR	OBSOLETE	TSSOP	PW	8		TBD	Call TI	Call TI	-40 to 85		
TLV2422MUB	ACTIVE	CFP	U	10	1	TBD	A42	N / A for Pkg Type	-55 to 125	9751401QHA TLV2422M	Samples
TLV2422QDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2422Q	Samples
TLV2422QDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	V2422Q	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "--" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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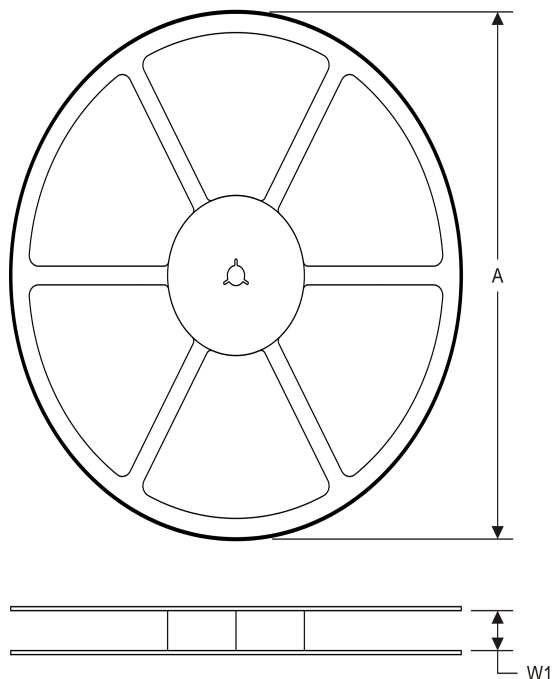
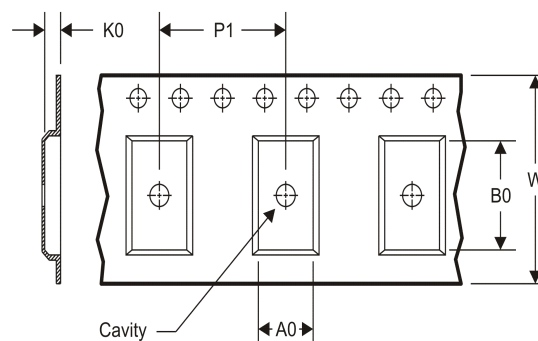
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TLV2422, TLV2422A, TLV2422AM, TLV2422M :

- Catalog: [TLV2422A](#), [TLV2422](#)
- Automotive: [TLV2422-Q1](#), [TLV2422A-Q1](#), [TLV2422A-Q1](#), [TLV2422-Q1](#)
- Military: [TLV2422M](#), [TLV2422AM](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2422AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2422AIPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TLV2422CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2422CPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TLV2422IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

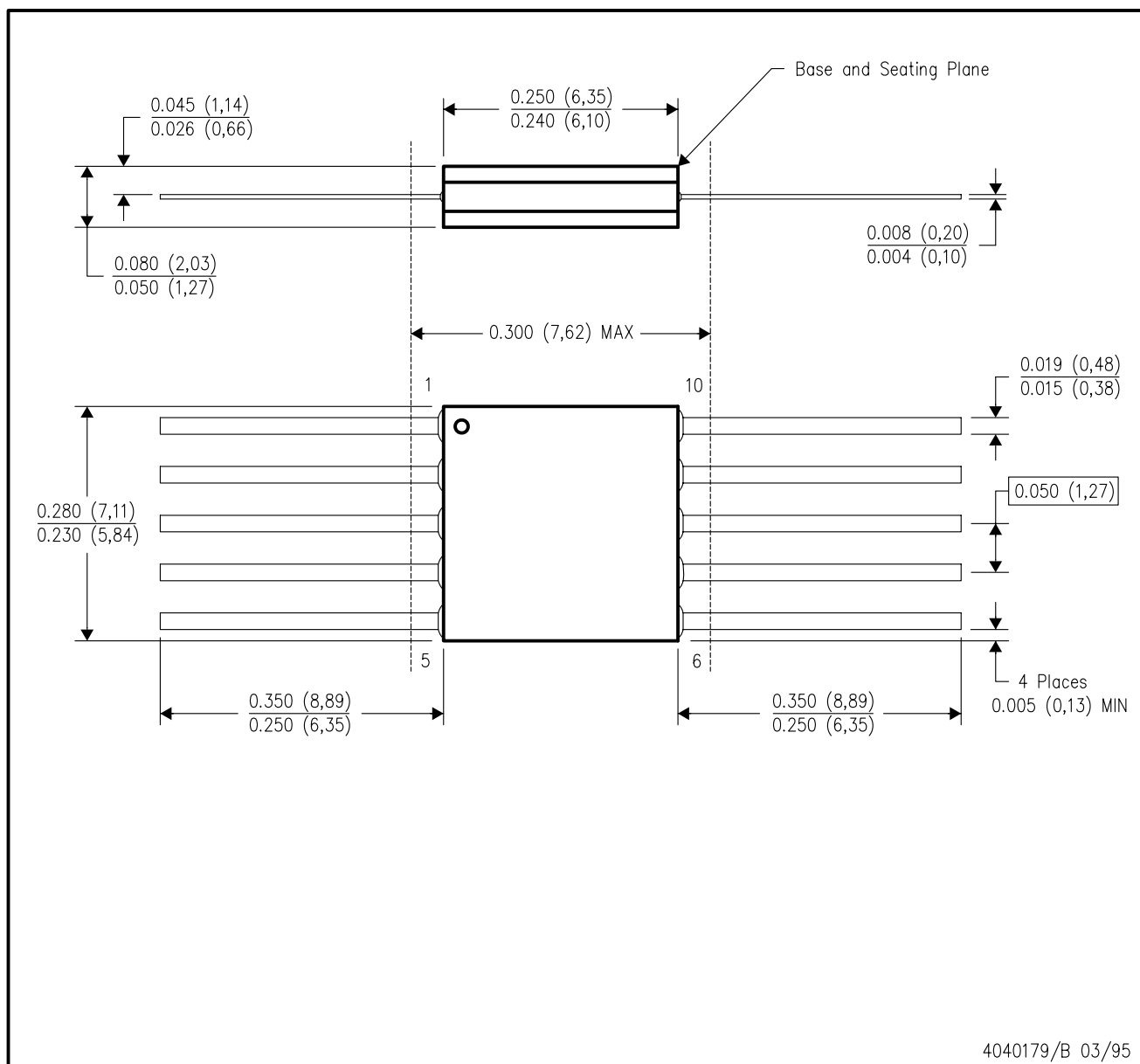


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2422AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2422AIPWR	TSSOP	PW	8	2000	367.0	367.0	35.0
TLV2422CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2422CPWR	TSSOP	PW	8	2000	367.0	367.0	35.0
TLV2422IDR	SOIC	D	8	2500	340.5	338.1	20.6

U (S-GDFP-F10)

CERAMIC DUAL FLATPACK

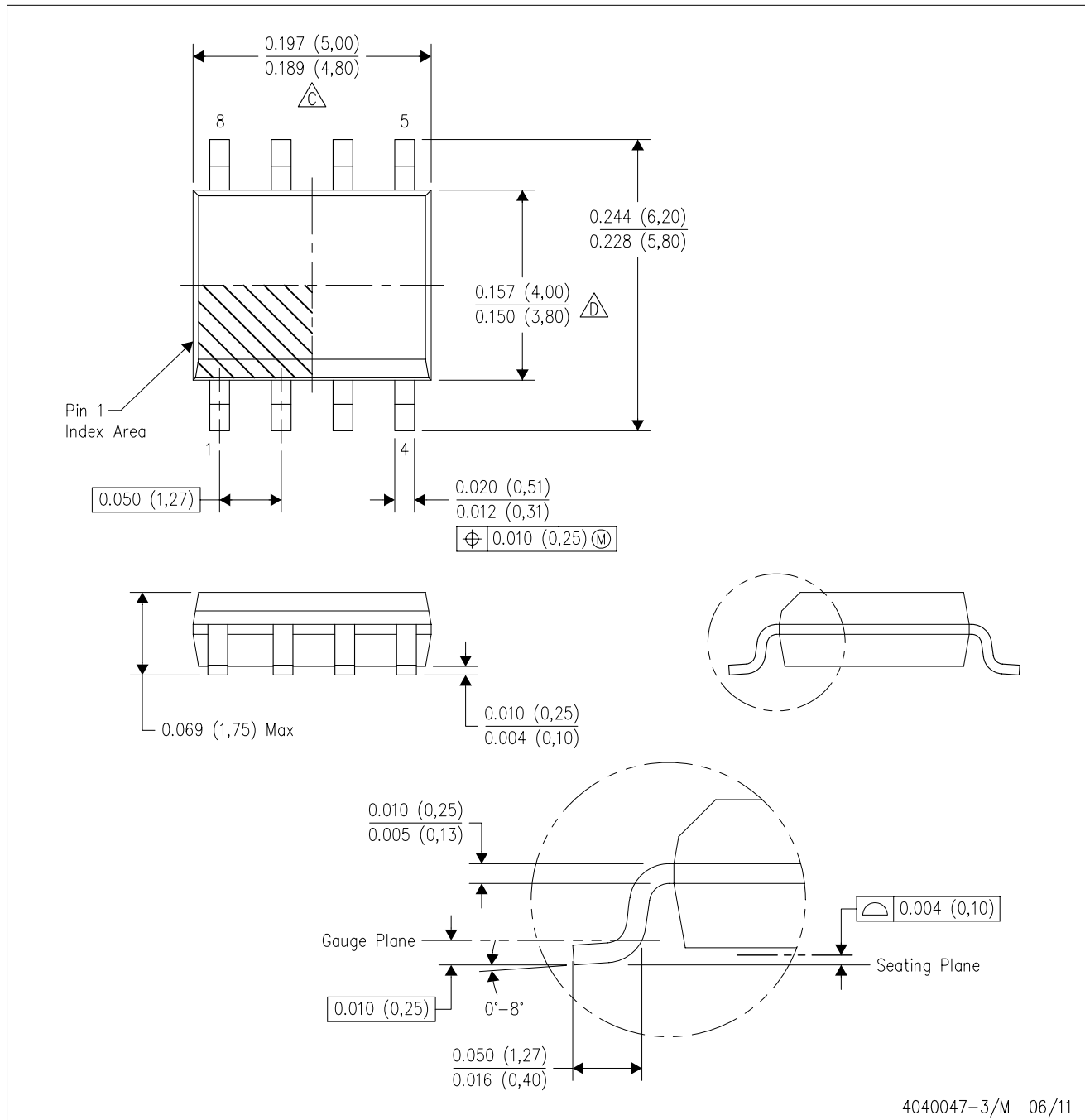


NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F10 and JEDEC MO-092AA

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AA.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE

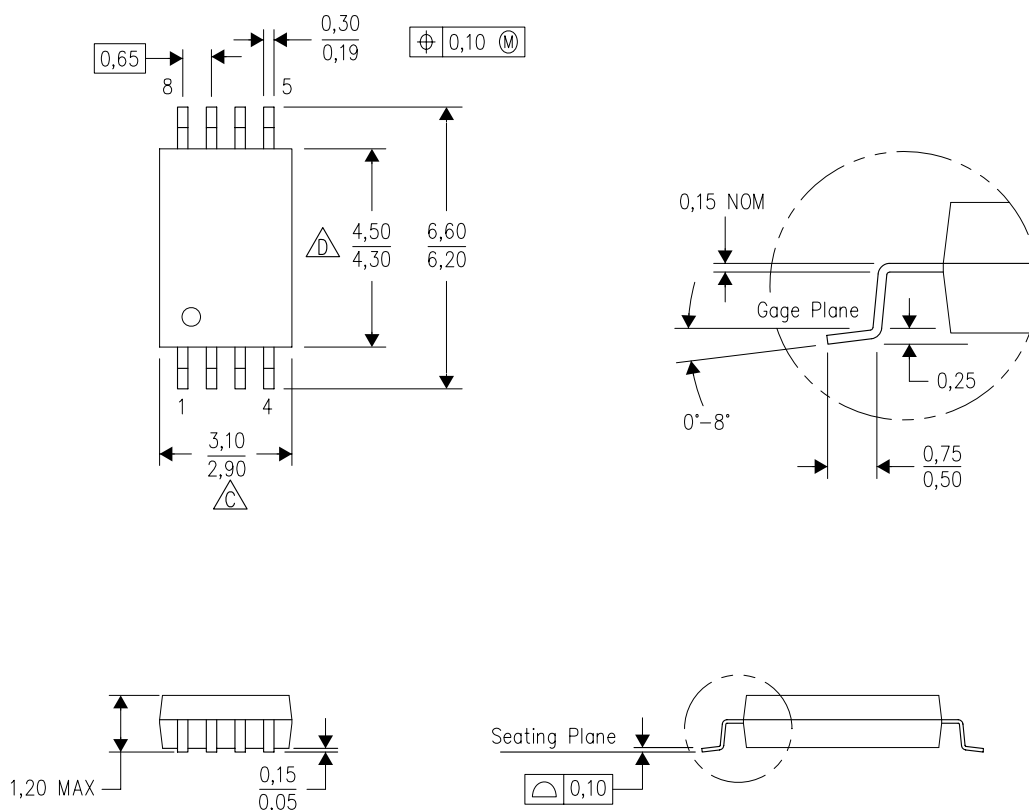


4211283-2/E 08/12

- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PW (R-PDSO-G8)

PLASTIC SMALL OUTLINE



4040064-2/G 02/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

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